Panasonic

Hall IC Series

Application Notes

Contents

The History of Development and Mass-Production

The mass production and shipment of our Hall IC series started in 1976. Since then we have successively improved their characteristics including miniaturization and SMD-ing (making the device surface-mountable) of the packages. And now we added newly developed Hall ICs (AN48800 series) to our Hall IC line-ups.

For your reference, we described bellow the history of Hall ICs in mass production, just-started mass production and under development.

■ The history of development and mass production of Hall ICs

AN48800A (2001) High sensitivity (6 mT) Low current consumption (10 µA)

DN8796MS (1996) Operating supply voltage 2.7 V to 14.4 V, alternating magnetic field operation
DN8798MS (1996) Operating supply voltage 2.7 V to 14.4 V, alternating magnetic field operation

DN8897/SE/S (1989) ← DN6847 Zero-cross type (option)
DN8899/SE/S (1989) ← DN6849 Zero-cross type (option)

DN6847/SE/S (1988) ← DN6851 Temperature characteristic and sensitivity improvement
DN6848/SE/S (1988) ← DN6852 Temperature characteristic and sensitivity improvement
DN6849/SE/S (1988) ← DN6853 Temperature characteristic and sensitivity improvement

DN6851 (1985) ← DN6838 Temperature characteristic and sensitivity improvement
DN6852 (1985) ← DN6839 Temperature characteristic and sensitivity improvement

The Hall ICs listed below are discontinued.
DN6834 (1979) ← DN834 Improved into 3-pin type
DN6837 (1979) ← DN837 Improved into 3-pin type
DN6838 (1979) ← DN838 Improved into 3-pin type
DN6839 (1979) ← DN839 Improved into 3-pin type
DN6835 (1979) ← DN835 Improved into 3-pin type
Linear type production are discontinued, use a Hall element and an operational amplifier.

DN834 (1976) One-way magnetic field operation, equipped with an output pull-up resistor, V_{CC} = 5 V
DN835 (1976) Linear output, V_{CC} = 5 V
DN837 (1976) One-way magnetic field operation, open collector output, V_{CC} = 5 V
DN838 (1976) Alternating magnetic field operation, equipped with an output pull-up resistor, V_{CC} = 5 V to 16 V
DN839 (1976) One-way magnetic field operation, open collector output, V_{CC} = 5 V to 16 V

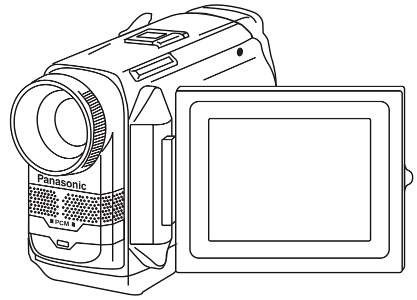
Quick Reference Table

Part No.	Operating magnetic field	Output type	Package	Operating supply voltage	Page
AN48800A	One-way	Open drain	MINI-3DRA	2.5 V to 3.5 V	22
AN48810A	One-way	CMOS inverter	SMINI-5DA	2.5 V to 3.5 V	26
DN8796MS	Alternating	With a pull-up resistor	MINI-3DA	2.7 V to 14.4 V	30
DN8797MS	One-way	With a pull-up resistor			32
DN8798MS	Alternating	Open collector			34
DN8799MS	One-way	Open collector			36
DN6847	Alternating	With a pull-up resistor	SSIP003-P-0000H	4.5 V to 16.0 V	45
DN6847S			ESOP004-P-0200A		
DN6847SE			SSIP003-P-0000J		
DN6848	One-way	Open collector	SSIP003-P-0000H	4.5 V to 16.0 V	49
DN6848S			ESOP004-P-0200A		
DN6848SE			SSIP003-P-0000J		
DN6849	Alternating	Open collector	SSIP003-P-0000H	4.5 V to 16.0 V	53
DN6849S			ESOP004-P-0200A		
DN6849SE			SSIP003-P-0000J		
DN6851	Alternating	With a pull-up resistor	SSIP003-P-0000H	3.6 V to 16.0 V	57
DN6852	One-way	Open collector	SSIP003-P-0000H	3.6 V to 16.0 V	60

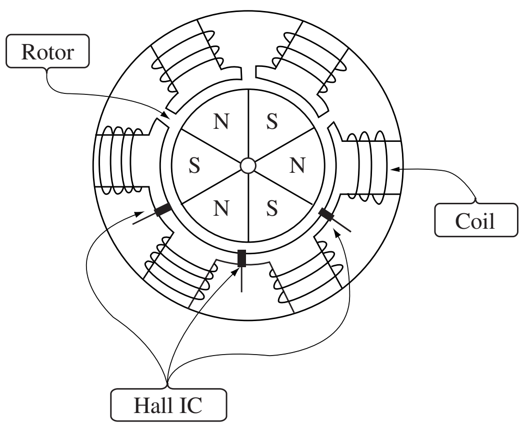
Hall IC Applications in Various Fields

Flip type cellular phone

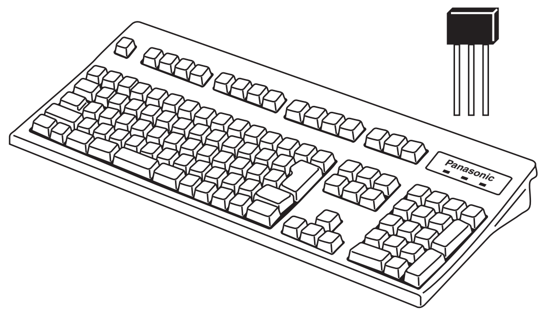
Video camera with LCD display



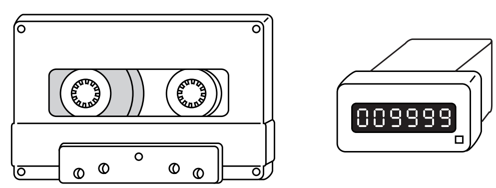
Brushless motor



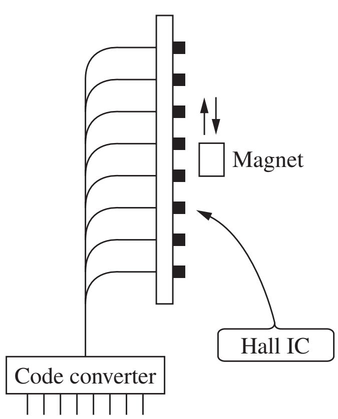
Key board



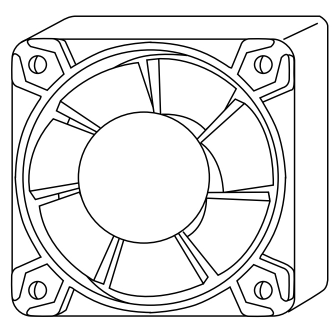
Tape counter for audio, Auto reverse sensor



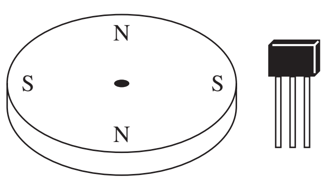
Position or level sensor



MPU fan motor



Rotary sensor



The Hall IC produced by Matsushita Electronics Corporation is made from silicon, same as general IC (Bipolar IC and CMOS IC). The sensor block and peripheral circuits (amplifier and Schmidt trigger) are designed on the same chip.

The construction of Hall IC and operating theory

The theory of Hall element is that the electrode A, B, C and D are made on a resistor (the same diffusion process as resistors of ICs) shown in figure 2-a; then the voltage is applied between A and B, and the current flows as a result; in this conditions, if magnetic flux is given vertically to the resistor, by Fleming's left hand rule (Shown in figure 1), force 'F' works from D to C direction, and the current density will be C > D between C and D, and potential difference will be generated. (Shown in figure 2-b.)

This phenomenon is called "Hall effect" and the potential difference is called Hall voltage. This phenomenon was discovered by Mr. E. H. Hall.

Regarding the performance of Hall element, the Hall voltage of compound semiconductor like GaAs, InAs, InSb (whose electron mobilities are large) is larger and more advantageous. Although Hall voltage of Si is small, the silicon Hall element can be made together with the amplifier circuit and Schmidt trigger circuit on the same chip due to using the bipolar diffusion process.

This is an easy-to-use sensor because the sensor block and peripheral circuit are built in on the same single chip.

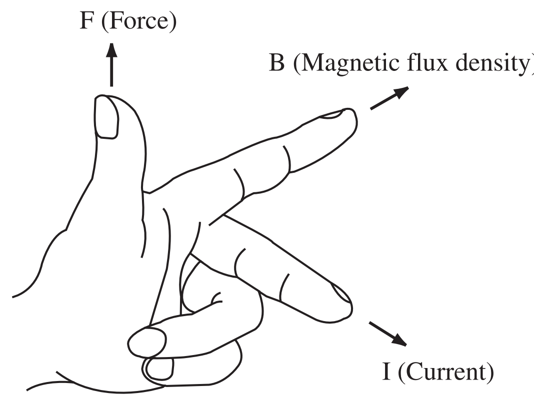


Figure 1. Fleming's left hand rule

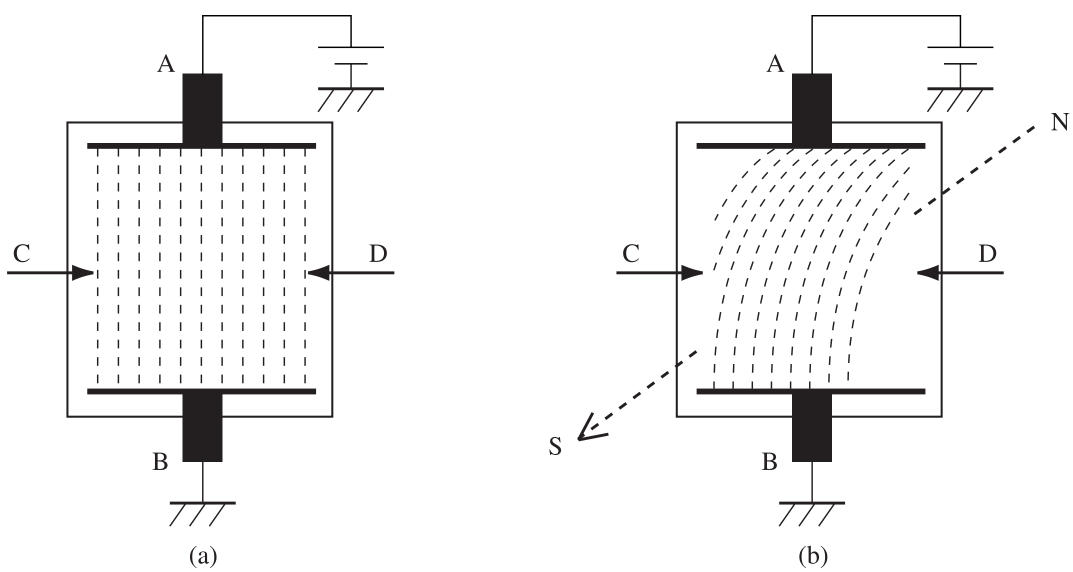


Figure 2. Operating theory of Hall IC

The Hall ICs are applied in the various fields.

Please design your products referring to the use method and remarks.

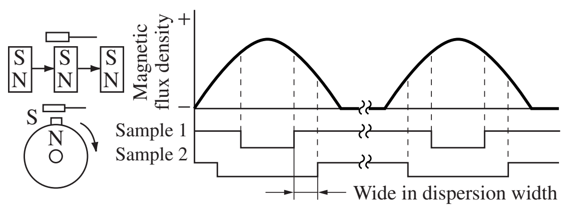
1. The application for FDD index sensor

To reduce the variation of the pulse position of index sensor, 2) of alternating field operation type is much better than 1) of one-way magnetic field operation type.

The accuracy will be increased if the changes of magnetic density at the changing point from S to N are steep.

Especially, the use of two magnets will be more efficient than using one magnet.

1) Unipolar
(One-way magnetic field operation type)



2) Bipolar
(Alternating magnetic field operation type)

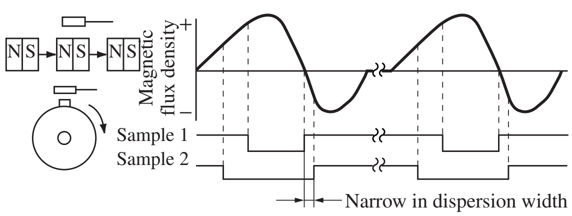


Figure 3

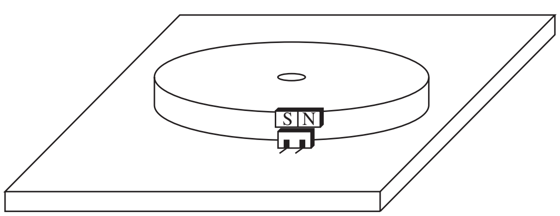


Figure 4

2. The application for a flip type cellular phone

Closing of a flip causes a signal to be transmitted to a microcomputer, then the power supply is turned off to save the power consumption.

Figure 5

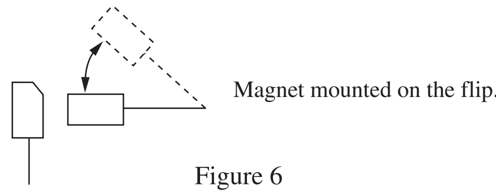


Figure 6

The Hall IC is a kind of high sensitivity, low current consumption and one-way magnetic field operation type. For example: AN48800 series.

3. The application for micro-switch

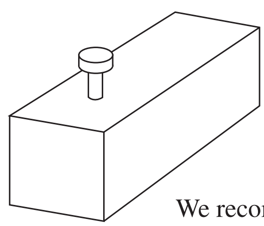


Figure 7

We recommend the alternating field operation to maintain the stroke accuracy and to make On/Off stroke small.

For example: DN6847, DN6849 etc.

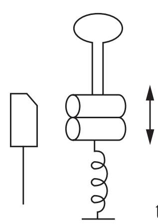
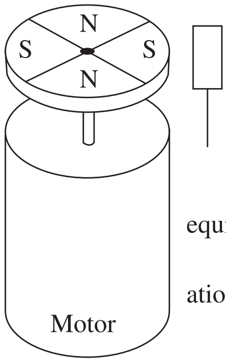


Figure 8

The two same size magnets are used to make a steep change of magnetic flux density.

Usually N-pole faces to Hall IC and let S-pole face to it for operation (switching).

4. The application for the detection of motor rotation



For washing machines, massage equipment of fan motors.

Hall ICs for alternating field operation type: DN6847, DN684S etc.

Figure 9

5. The application for the coil current phase switching sensor of brushless motor

According to the rotation of magnet, the coil current phase is switched.

The Hall ICs of the alternating magnetic field operation type are DN6847, DN6849.

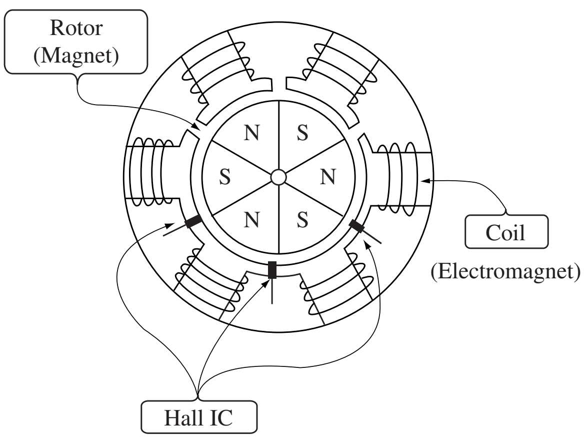


Figure 10

6. The application for:

- The tape counter for audio equipment
- Auto reverse sensor
- Auto reverse and auto stop sensor for answering machine

This function is used to detect the tape end by the rotating magnet according to tape running. In case of tape end detection, it couldn't be decided whether the tape has stopped at S-pole or N-pole, so count it as shown in figure 12 or count the number of pulse or pulse width per fixed interval of time with a microcomputer.

The recommendable ICs for alternating field operation type are DN6847, DN6849.

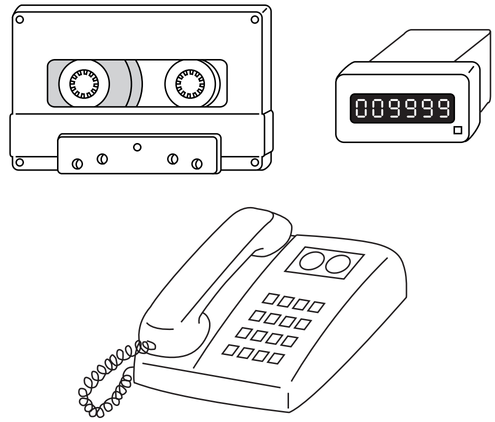


Figure 11

As shown in figure 12, this is used with 'C' cut, so that it becomes low-level when the magnet stops. ('R' is pulled up to 'V_{CC}' and high-level is obtained when the magnet stops.)

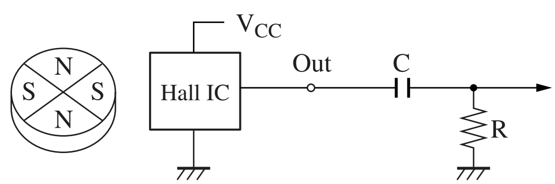


Figure 12

7. The application for a box fan motor

The fan motors of two-phase systems.

The fan motor of box type is usually the brushless motors of two-phase systems.

The Hall IC detects the rotary position of rotor magnet like the brushless motors of three-phase systems.

The recommendable ICs for alternating field operation type are DN6847, DN6849, DN8798MS.

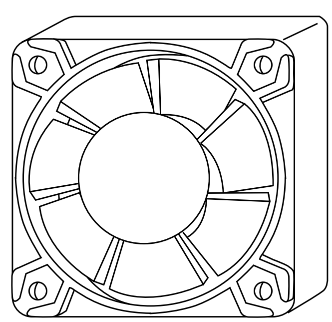


Figure 13

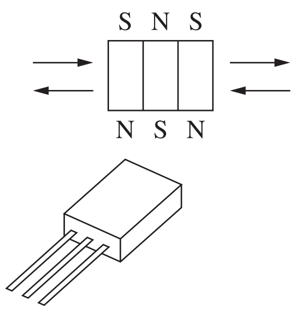
8. The application for the reciprocating motion switch and sensor

If the ON-position of the Hall IC's output may well be coarse in using Hall IC for a reciprocal switch or sensor, the one-way type Hall IC like DN6848 is recommended.

Use the alternating field operation type (DN6847, DN6849) to improve the accuracy of the ON-position.

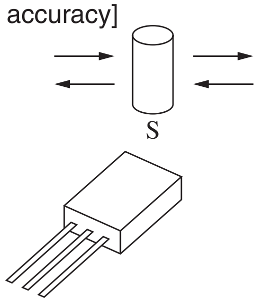
The output of the Hall IC will be switched on only when the S-pole goes across the Hall IC if the 3 magnets are arranged as shown below.

[Excellent in positional accuracy]



Hall IC of alternating magnetic field operation type

[Coarse in positional accuracy]



Hall IC of one-way magnetic field operation type

Figure 14

9. The distinction of magnet S- or N-pole

Prepare the Hall IC (DN6848) and attach the LED to Hall IC's output as shown below.

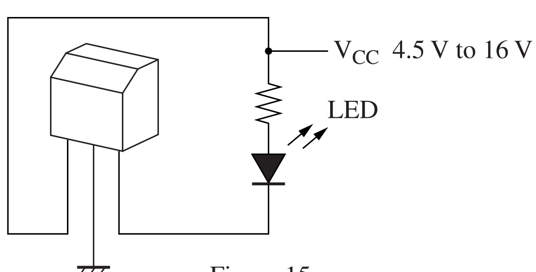


Figure 15

If the magnet approaches the marking side of Hall IC and LED lights up, the near side to the Hall IC is the S-pole.

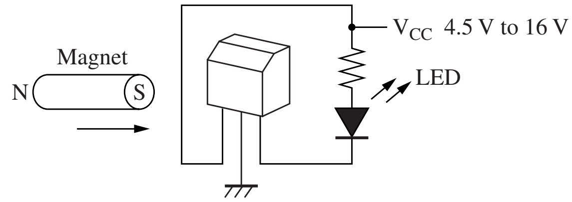


Figure 16

Paint the S-pole, then you can surely find which is which. If you use short magnet, it's convenient to do like figure 17.

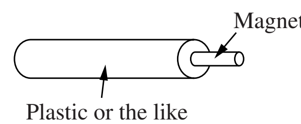


Figure 17

The S-pole of the other magnet will easily be found, if the N-pole is protruded.

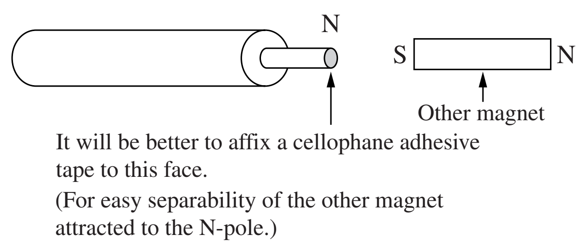


Figure 18

10. In case of a little bit insufficient magnet flux density

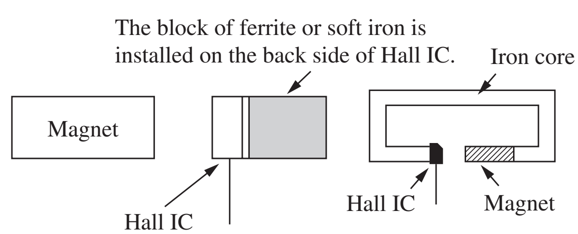


Figure 19

The flux density of magnet on the Hall IC is a little bit increased by the method of figure 19 because the line of magnetic force easily gathers at the blocks of ferrite or soft iron in which the magnetic flux lines apt to go through. Run the mass production after fully confirming the flux density of the magnet to be actually used through taking its data.

The Explanation

The Hall IC converts the magnetic force to the electric signal, and outputs it. It is essential to know not only the characteristics of Hall IC but the characteristics of magnet.

As the characteristics of magnet differs depending on their materials, shapes and magnetic conditions, please take the data of characteristics of the magnet to be used. This is the most important conditions to produce the highly reliable equipment.

1. How to read the Hall IC specifications

1.1 The example of products specifications

Electrical characteristics example for a product with a pull-up resistor (T_a = 25°C)

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Operating magnetic flux density	$B_{1(L-H)}$	V_{CC} = 12 V	–17.5	–5.0	—	mT
	$B_{2(H-L)}$	V_{CC} = 12 V	—	5.0	17.5	mT
Hysteresis width	BW	V_{CC} = 12 V	7.0	10.0	—	mT
Output voltage	V_{OL}	V_{CC} = 4.5 V to 16 V, I_O = 12 mA, B = 17.5 mT	—	—	0.4	V
	V_{OH}	V_{CC} = 16 V, I_O = –30 μA, B = –17.5 mT	14.6	—	—	V
		V_{CC} = 4.5 V, I_O = –30 μA, B = –17.5 mT	2.9	—	—	V
Output short-circuit current	$-I_{OS}$	V_{CC} = 16 V, V_O = 0 V, B = –17.5 mT	0.4	—	0.9	mA
Supply current	I_{CC}	V_{CC} = 16 V	—	—	6	mA
		V_{CC} = 4.5 V	—	—	5.5	mA

Note) For circuit currents, '+' denotes current flowing into the IC and '–' denotes current flowing out of the IC.

Electrical characteristics example for a product with an open collector output (T_a = 25°C)

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Operating magnetic flux density	$B_{1(L-H)}$	V_{CC} = 12 V	–17.5	–5	—	mT
	$B_{2(H-L)}$	V_{CC} = 12 V	—	5	17.5	mT
Hysteresis width	BW	V_{CC} = 12 V	7	10	—	mT
Output voltage	V_{OL}	V_{CC} = 4.5 V to 16 V, I_O = 12 mA, B = 17.5 mT	—	—	0.4	V
Output current	I_{OH}	V_{CC} = 4.5 V to 16 V, V_O = 16 V, B = –17.5 mT	—	—	10	μA
Supply current	I_{CC}	V_{CC} = 16 V	—	—	6	mA
		V_{CC} = 4.5 V	—	—	5.5	mA

Note) For circuit currents, '+' denotes current flowing into the IC and '–' denotes current flowing out of the IC.

1.2 How to read the example of products specification

Parameter	Descriptions
Operating magnetic flux density B_{H-L}	Flux density that changes the output from high-level to low-level.
Operating magnetic flux density B_{L-H}	Flux density that changes the output from low-level to high-level.
17.5 mT −17.5 mT	The mark is '+' when the face side of Hall IC is S-pole (accordingly the back-side is N). Conversely it is '–' when the face side is N-pole (the back-side is S).
B_{H-L} 17.5 mT	The Hall IC's output goes from high-level to low-level if the flux density is 17.5 mT or more.
B_{L-H} −17.5 mT	The Hall IC's output goes from low-level to high-level if the flux density is −17.5 mT or less.
Operating magnetic flux density	Operational flux density is stipulated by the flux density applied to the chip surface of Hall IC. It is not the flux density at the surface of the magnet.
Hysteresis width	The differences between B_{H-L} and B_{L-H} .

Note) Unit of flux density: 1 Gauss = 10^{-4} T (tesla) (International Unit System (SI))

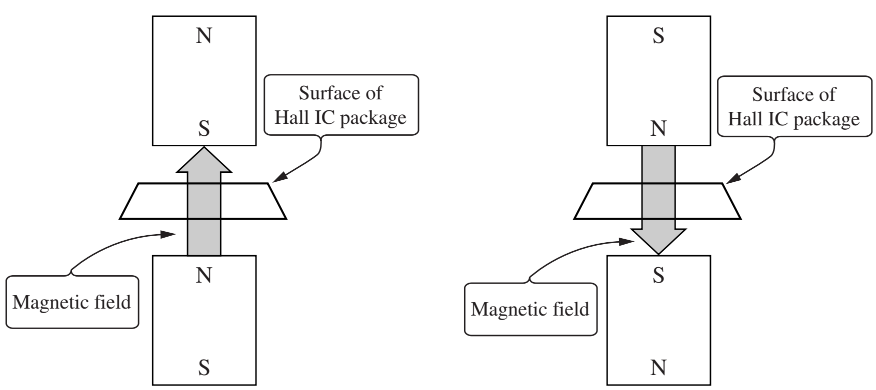
The example of a product with a pull-up resistor

Parameter	Descriptions
Output voltage: V_{OL}	It is stipulated that when output intake current is 12 mA, $V_{CE(sat)}$ of the output transistor in the IC should be 0.4 V or less. To reduce the V_{OL} to 0.4 V or less, it is necessary to reduce the intake current to 12 mA or less. (Please use the output current of 12 mA or less.)
Output voltage: V_{OH}	Following is stipulated: 14.6 V or more if output level is high-level and V_{CC} = 16 V; 2.9 V or more if V_{CC} = 4.5 V.
Output short-circuit current: I_{OS}	Specifies the current when the output pin is short-circuited to GND. This is equivalent to stipulating the resistance value of the built-in pull-up resistor. ($R = V_{CC} / I_{OS}$)
Supply current: I_{CC}	The value of current flowing into IC, when output is high-level.

The example of open collector type (the difference from with the pull-up resistor)

Parameter	Descriptions
Output current: I_{OH}	The stipulation for the maximum value of leak current of the built-in output transistor.

1.3 The definition of '+' and '–' in the operating flux density



1) In case the magnetic flux density is plus 2) In case the magnetic flux density is minus

Figure 20

Note) Except the mini-mold package, the IC chip face comes to the face (type name marked) of the package.

2. Alternating magnetic field operation IC

The Hall IC that operates in the magnetic field which changes continuously S → N → S → N.

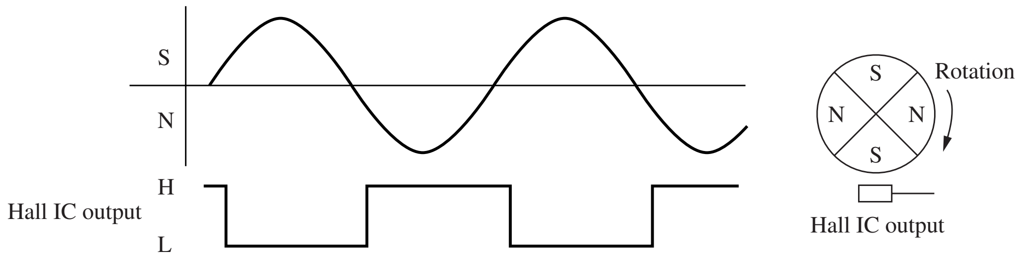


Figure 21

3. One-way magnetic field operation IC

The Hall IC that operates only by S-pole or N-pole.

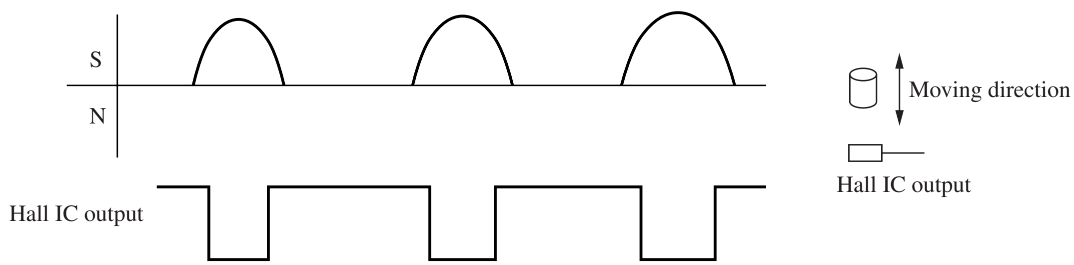


Figure 22

4. Measuring method for the operating flux density

Use the electromagnet whose sectional area is large enough to be free from any effects of the IC's location. By using above mentioned electromagnet, it is able to measure the sensitivity of Hall IC without regard to IC's distances from magnet.

<Measuring method>

1) Please prepare the data of the current which flows in the coils and responding flux density.
2) By changing of the power supply for the magnet, you can change the current flows in coils. In consequence, you can change the flux density of the electromagnet.
3) The current which flows in the coil could be read as the voltage which was generated between both ends of the resistor. Adjust the value of this resistor so that 100 mT becomes 1.000 V. From the above mentioned process, you could be able to read by the voltmeter as 1 mV = 0.1 mT. (Unless the relation between flux density and voltage is determined beforehand, it is impossible to gain the necessary linearity.)

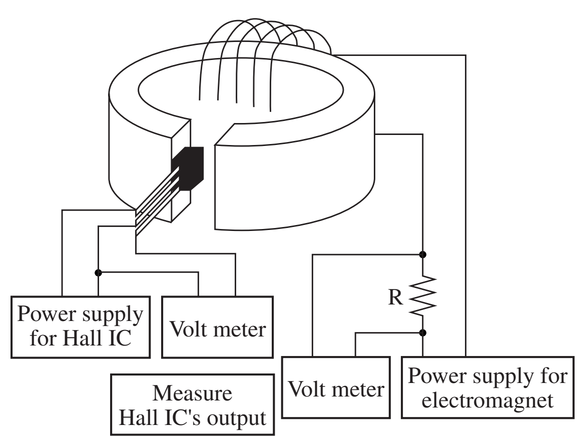


Figure 23

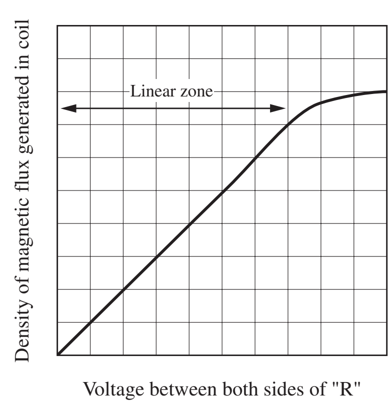


Figure 24

5. About the sensitivity variation

Hall IC has the variation in its operating sensitivities. Design the equipment so as to be able to absorb or ignore such variation.

5.1 Alternating magnetic field operation type

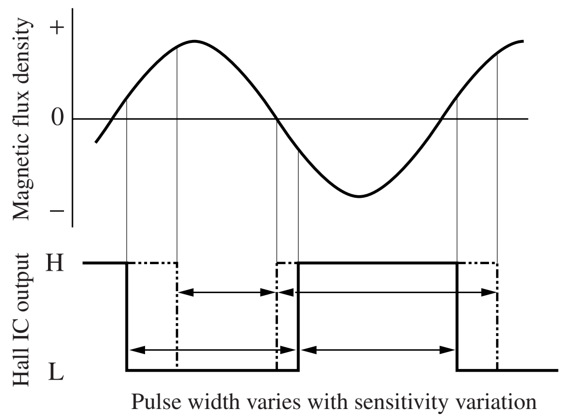


Figure 25

If you use only the rise time or fall time wave for the detection of the rotation frequency, please use the DN6847, DN6849 even if above mentioned variation will happen.

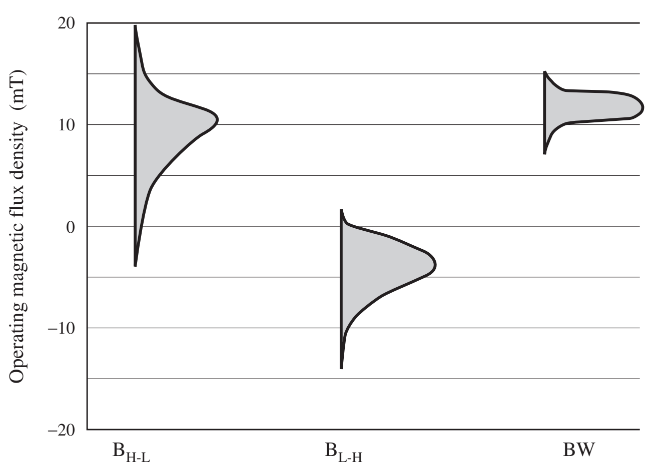


Figure 26. Operating sensitivity distribution of DN6847

• DN6847/SE/S, DN6849/SE/S

Operating magnetic flux density — Ambient temperature

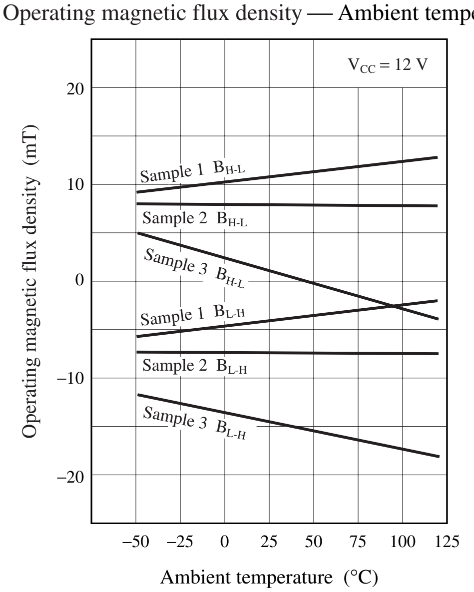


Figure 27. Temperature characteristics

5.2 One-way magnetic field operation type

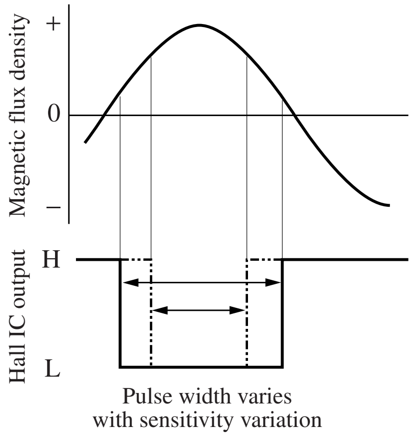


Figure 28

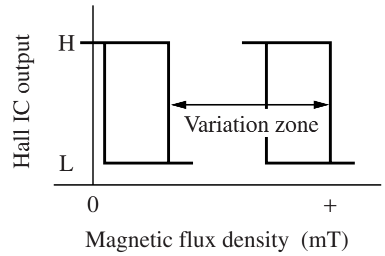


Figure 29

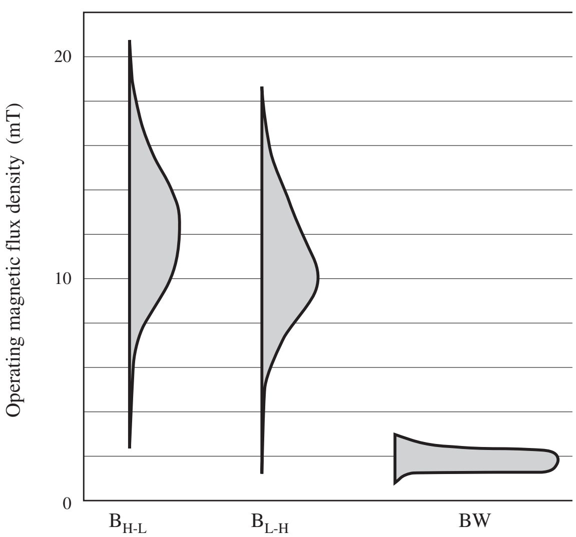


Figure 30. Operation sensitivity distribution of DN6848

• DN6848/SE/S

Operating magnetic flux density — Ambient temperature

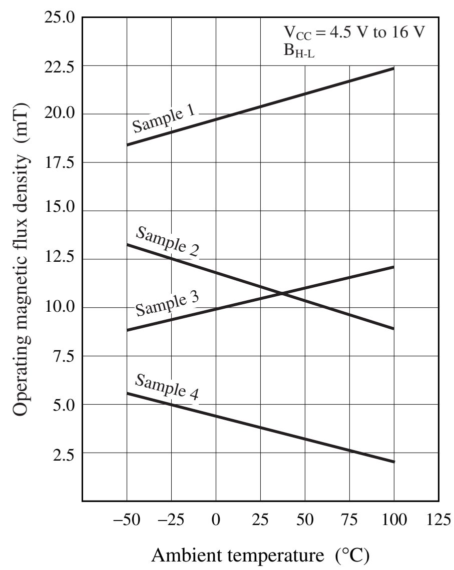


Figure 31. Temperature characteristics

5.3 Maximum operating frequency

In Hall IC, the power output will be in the shape of rectangular wave, because of Schmidt trigger, even if the magnet rotation frequency is small.

Actually, if the output wave is enlarged, the delay time occurs in both rise and fall times as shown in figure 33-2 'a' and 'c'. At quicker change more than this delayed time, the IC output can not reach high-level or low-level. So, please use lower frequency than this time.

Though, when the rise and fall time is supposed to be 3 µs + 40 ns ≈ 4 µs, maximum frequency will be 250 kHz, please use the frequency within 100 kHz with a margin.

For example,

If the disc type magnet rotates with 60 000 rpm (rotation frequency per minute)

60 000 ÷ 60 = 1 000 rotations/second

Suppose the number of magnetic pole is 20 poles at the most.

1 000 × 20 ÷ 2 = 10 000 (Hz) (1 Hz at S and N)

Therefore, the average operational speed of Hall IC is high enough for the mechanism and has enough capacity.

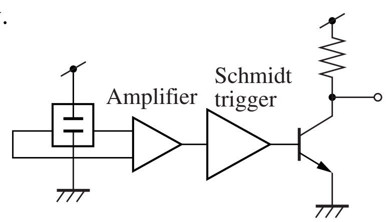


Figure 32. Block diagram of IC interior

Note) Because AN48800 series runs in an intermittent operation, time of the intermittent time or more is necessary for the operating time.

• Switching characteristic of Hall IC

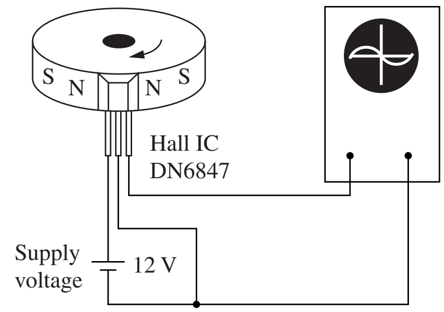
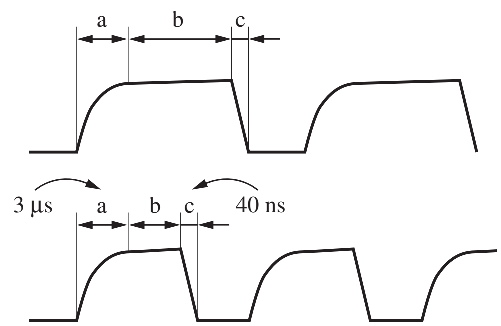


Figure 33-1. Measuring circuit



In case the supply voltage is constant, only the space 'b' changes with variation in the rotation frequency.

(In case of V_{CC} = 12 V, a = 3 µs (typ.), c = 40 ns (typ.))

Figure 33-2. Switching waveforms

5.4 How to take magnet data

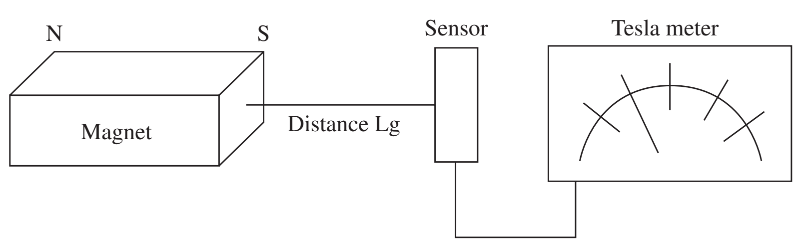


Figure 34

1) Remove gradually the sensor from surface of magnet, measure the data of flux density in each position. (figure 35)
2) Take the variation data of magnetizer condition. (figure 35)
3) Take the temperature characteristics of above 1) and 2). (figure 36)

5.4 How to take magnet data (continued)

• Magnet data example 1 (variation of magnetization)

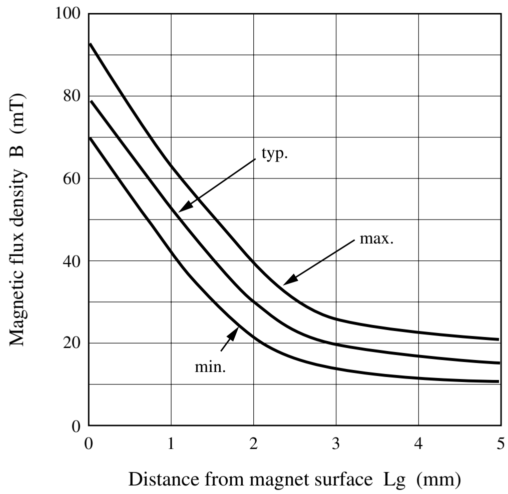


Figure 35

• Magnet data example 2 (Temperature characteristics)

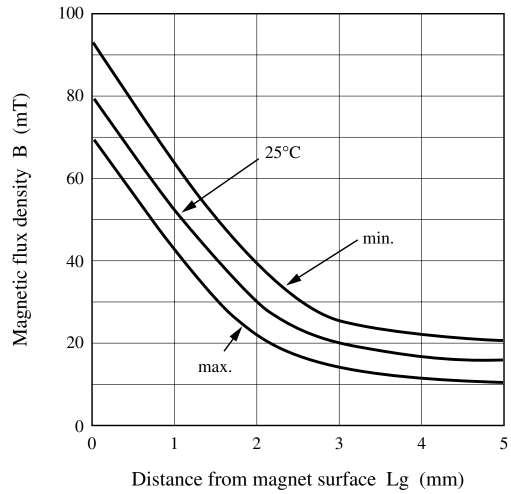


Figure 36

Generally, the rare earth magnet is ferromagnetism. The ferrite type can't gain the large flux density. However, this type is economical to use.

Even the magnet size is the same, the flux density depends on the each material.

• The comparison between the ferrite magnet and manganese aluminium magnet.

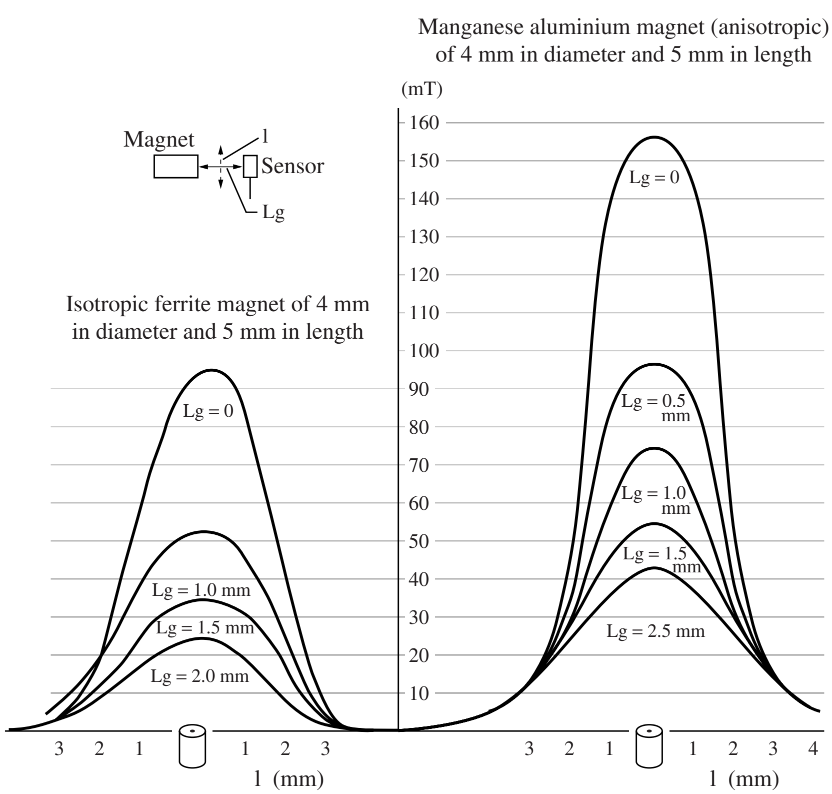


Figure 37

Even when the size is the same, the characteristics differs in material.

Even the material is the same, the flux density differs in the shape and the number of magnetizing pole.

Please design after testing of the characteristics of magnet which will be really used.

5.4 How to take magnet data (continued)

<Reference data>

Measured example of manganese aluminium magnet

Axial-direction space-magnetic-flux density of axial type magnet (07BR)

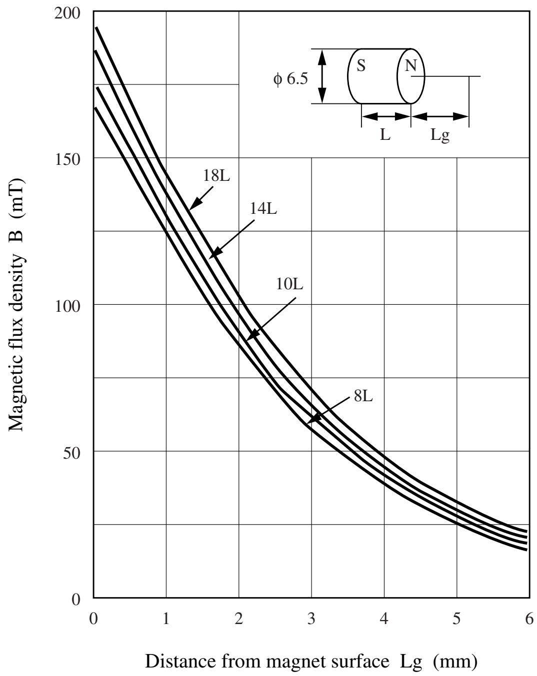


Figure 38

Axial-direction space-magnetic-flux density of axial type magnet (04BR)

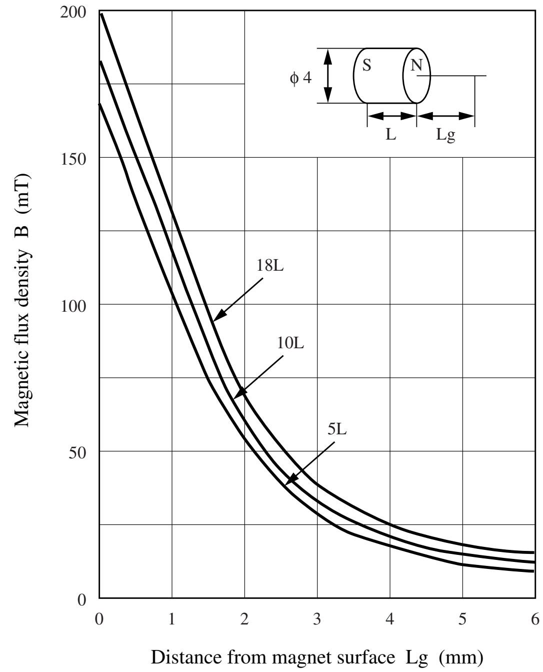


Figure 39

Radial-direction space-magnetic-flux density of ring type magnet

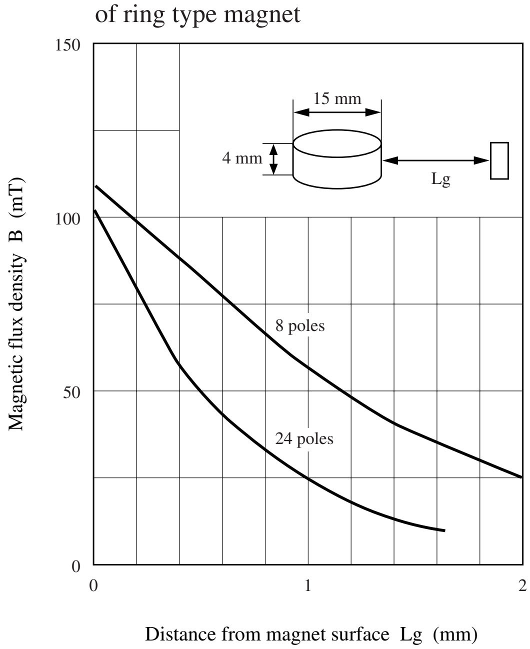


Figure 40

Radial-direction space-magnetic-flux density (on magnet surface) of ring type magnet

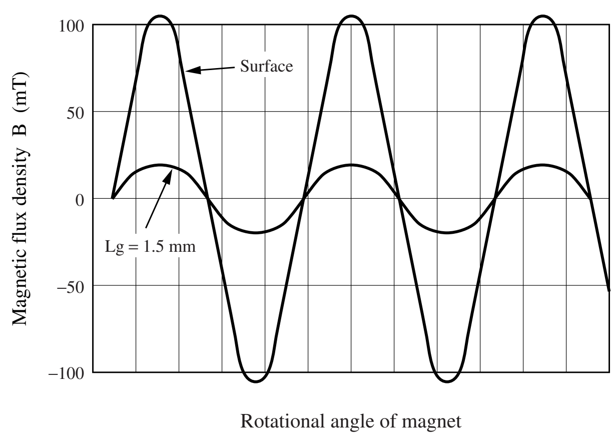


Figure 41

If you could prepare the data of the magnet described above, you can judge on the graph paper whether or not this Hall IC can be used.

And if you don't conduct above survey, it may occur in mass production line that the IC can't operate due to the insufficient magnetic flux density.

5.5 Operating point of Hall IC

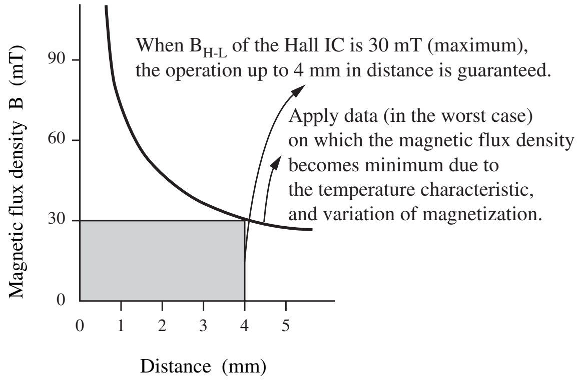


Figure 42

The sensitivities of Hall ICs don't mean the value on the surface of Hall ICs, but the value on the chip of Hall ICs.

The operation sensitivity of Hall IC varies depending on the temperature characteristic or mechanical/ thermal stress. Take sufficient margin.

Sample)

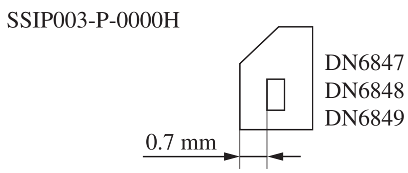


Figure 43

When the distance between the magnet surface and the surface of Hall IC package is 1 mm.

1 mm + 0.7 mm = 1.7 mm

Please don't forget to measure the value of actual measurement on magnet flux density. Especially, though the type of disc-like magnetized has large flux density, it may be reduced extremely if the distance is increased only slightly.

The Hall ICs are often used to detect movement. In such cases, the position of the Hall IC may be changed by exposition to shock or vibration over a long period of time, and it causes the detection level change. To prevent this, fix the package with adhesives or fix it on a dedicated case.

1. A case using an adhesive

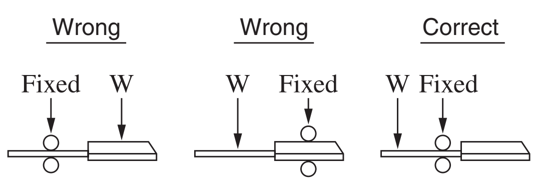
Some kinds of adhesive generate corrosive gas (such as chloric gas) during curing. This corrosive gas corrodes the aluminum on the surface of the Hall IC, and may cause a functional defect of disconnection.

If Hall IC is to be sealed after installation, attention should be given to the adhesive or resin used for peripherals and substrate cleaner, as well as to the adhesive used for Hall IC installation. Please confirm the above matter to those manufacturers before using.

We could not select the specified adhesive, for we find it difficult to guarantee the ingredient of each adhesive.

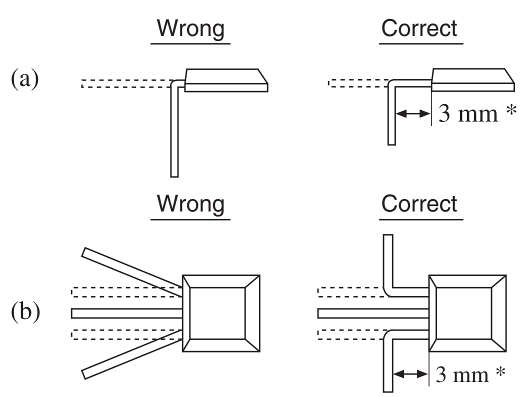
2. A case bending lead wire

Bend the lead wire without stressing the package.



Bending method of lead wire

Figure 44



Bending position of lead wire

*: The distance can be within 3 mm, if no stress is applied to the resin mold by tightly fixing the lead wires with a metallic mold or the like.

Figure 45

3. Power supply line/Power transmission line

If a power supply line/power transmission line becomes longer, noise and/or oscillation may be found on the line. In this case, set the capacitor of 0.1 μF to 10 μF near the Hall IC to prevent it.

If a voltage of 18 V or more is thought to be applied to the power supply line (flyback voltage from coil or the ignition pulse, etc.), avoid it with external components (capacitor, resistor, Zener diode, diode, surge absorbing elements, etc.).

4. On mounting of the surface mount type package (ESOP004-P-0200A, MINI-3DA)

Set pin 2 of the ESOP004-P-0200A package open, or connect it to GND. The IC will be damaged if it is connected to V_{CC} .

When mounted on the printed circuit board, the Hall IC may be highly stressed by the warp that may occur from the soldering. This may also cause a change in the operating magnetic flux density and a deterioration of its resistance to moisture.

Figure 46

5. V_{CC} and GND

Do not reverse V_{CC} and GND. If the V_{CC} and GND pins are reversely connected, this IC will be destroyed. If the IC GND-pin voltage is set higher than other pin voltage, the IC configuration will become the same as a forward biased diode. Therefore, it will turn on at the diode forward voltage (approximately 0.7 V), and a large current will flow through the IC, ending up in its destruction. (This is common to monolithic IC.)

6. Cautions on power-on of Hall IC

When a Hall IC is turned on, the position of the magnet or looseness may change the output of a Hall IC, and a pulse may be generated. Therefore, care should be given whenever the output state of a Hall IC is critical when the supply power is on.

7. Fixing a Hall IC

When the Hall IC of an insertion type package installed by soldering the lead wire only is to be used under vibration, fix it firmly with a holder. Otherwise, vibration may cause metal fatigue in the lead wire of Hall IC, resulting in wire breakage.

8. On fixing a Hall IC to holder

When a Hall IC is mounted on the printed circuit board with a holder and the coefficient of expansion of the holder is large, the lead wire of the Hall IC will be stretched and it may give a stress to the Hall IC.

If the lead wire is stressed intensely due to the distortion of holder or board, the adhesives between the package and the lead wire may be weakened and cause a minute gap resulting in the deterioration of its resistance to moisture.

Sensitivity may also be changed by this stress.

9. On using flux in soldering

Choose a flux which does not include ingredients from halogen group, such as chlorine, fluorine, etc. The ingredients of halogen group may enter where the lead frame and package resin joint, causing corrosion and the disconnection of the aluminum wiring on the surface of an IC chip.

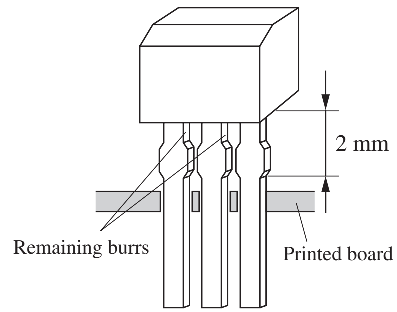
10. In case of the magnetic field of a magnet is too strong

Output may be inverted when applying a magnetic flux density of 100 mT or more. Accordingly, magnetic flux density should be used within the range of 100 mT.

11. On mounting , deburring and soldering of insertion type package

If the leads of a Hall IC in an insertion type package are inserted up to their root part through holes on the printed circuit board, abnormal stress is applied to the package and the reliability of the Hall IC is likely to deteriorate. So, when mounting each Hall IC of the insertion type, insert the leads in due degree at which the bottom face of the package is separated at least 2 mm from the top face of the PCB.

Also note that burrs of epoxy resin may be left sticking to the lead wires. (We are trying to remove such burrs as much as possible in the deburring process, but in some cases, they are not perfectly removable.)



When soldering the leads, remenber to separate the soldering position by 2 mm or more from the resin part of the package.

Figure 47

12. On surface treatment of mini-mold package

Surface treatment is available in either smooth or dull finish.

13. On soldering of the surface mount type package

Surface mounting type Hall ICs are apt to change its electrical characteristics due to the stress from soldering at mounting. Therefore, avoid the mounting by flow (dipping) and a soldering iron. Please mount it by reflow soldering abiding by its recommended conditions.

Trouble Shooting

When using Hall ICs, it is possible to prevent trouble beforehand by merely taking slight measures. To make the concerned equipment trouble-free, design it by referring to the examples of Hall IC trouble cases listed below and the cautionary instructions described later.

■ Most frequently occurred troubles

[Case 1] The operation of every Hall IC manufactured by way of trial was normal, but some Hall ICs put to mass production did not operate.

(Causes)
- The magnetic flux density of the magnet was insufficient.
- The temperature characteristics of the Hall IC and the magnet were ignored.

(Reasons)
- There was no data on the magnetic flux density of the magnet, and mass production was conducted in way of referring to just the equipment used in design and test production.
- In some ferrite magnets, the magnetic flux density drastically decreases at the high temperature side. But this property was not duly taken into consideration.
- The magnetic flux density was insufficient because the distance was set between the magnet and Hall IC package surface, and the distance to the sensor was not considered.

(Remedial measures)
- The magnet was exchanged to the magnet of large magnetic flux density.
- A block of ferrite or soft iron was affixed to the reverse of the Hall IC.
- The distance between the magnet and the Hall IC was diminished.

■ Trouble cases occurred less frequently but furnishes useful hints

[Cases 2] Some Hall ICs became inoperative on the market.

(Causes)
- The materials of the adhesive agents and the resin molds used for fixation of the Hall ICs subsequently generated hydrogen gas and other halogen gas. This gas intruded into the IC interior and corroded the aluminum wires on the IC surface.

(Remedial measures)
- We ceased to use those resin materials which generate such gas as is corrosive to metals.

[Cases 3] Some Hall ICs became inoperative on the market.

(Causes)
- The surge voltage ascribable to the counter electromotive force of motors and solenoids was applied to these Hall ICs and it broke the IC wires because the Hall ICs were being used in the vicinity of motors and solenoids.

(Remedial measures)
- The power supply line was separated from those of the motors and the solenoids.
- Surge absorbing elements were additionally inserted in the Hall ICs.

[Cases 4] Many defective products were detected in the mass production process.

(Causes)
- Abnormal stress was applied to many Hall ICs and their sensitivity changed because no jig was used in the lead wire bending process.

(Remedial measures)
- We introduced a new method of lead forming by a jig so that abnormal stress is never applied to each IC.

[Cases 5] Many defective products were found in the market.

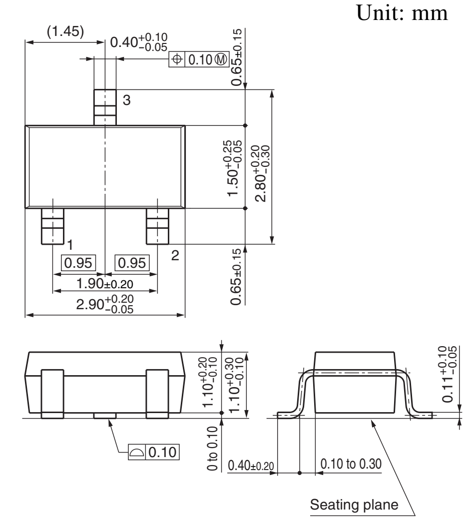
(Causes)
- The chloric solvent included in the flux used for the soldering work gradually intruded into the IC interior with the lapse of time, and corroded the aluminum wires on the chip surface.

(Remedial measures)
- Choose a flux which does not include ingredients from the halogen group, such as chlorine, fluorine and the like.

Individual Specification

AN48800A

Low current consumption, high sensitivity CMOS Hall IC One-way magnetic field operation



MINI-3DRA (Lead-free package)

■ Overview

The AN48800A is a Hall IC (a magnetic sensor) which has 2 times or more sensitivity and a low current consumption of about one three-hundredth compared with our conventional one.

In this Hall IC, a Hall element, a offset cancel circuit, an amplifier circuit, a sample and hold circuit, a Schmidt circuit, and output stage FET are integrated on a single chip housed in a small package by IC technique.

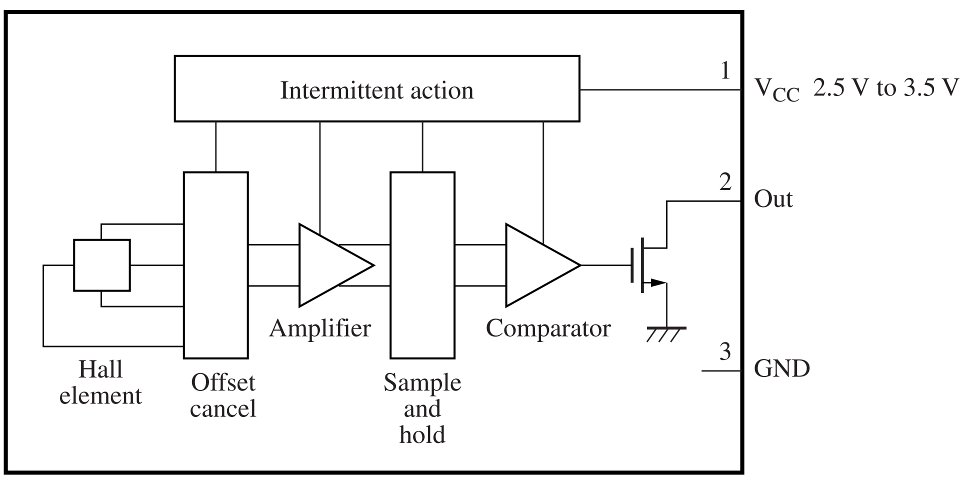
■ Features

- High sensitivity (6 mT max.) due to offset cancel circuit and a new sample and hold circuit
- Small current by using intermittent action
- Small package (SMD)
- Open drain output

■ Applications

- Flip type cellular phone, digital video camera

■ Block Diagram



Note) The magnetism detection time should be longer than one intermittent action cycle (On = 200 µs and Off = 51 ms).

■ Pin Descriptions

Pin No.	Symbol	Description
1	V_{CC}	Power supply
2	Out	Output
3	GND	Ground

■ Absolute Maximum Ratings

Parameter	Symbol	Rating	Unit
Supply voltage	V_{CC}	5	V
	V_{OUT}	5	V
Output current	I_O	30	mA
Power dissipation	P_D	60	mW
Operating ambient temperature	T_{opr}	−20 to +75	°C
Storage temperature	T_{stg}	−55 to +125	°C

Note) 1. Except for the operating ambient temperature and storage temperature, all ratings are for T_a = 25°C.
2. The reverse insertion of this IC will cause its breakdown.
3. It will operate normally in several tens of ms after power on.
4. This IC is not suitable for car electrical equipment.

■ Recommended Operating Range

Parameter	Symbol	Range	Unit
Supply voltage	V_{CC}	2.5 to 3.5	V

■ Electrical Characteristics at T_a = 25°C

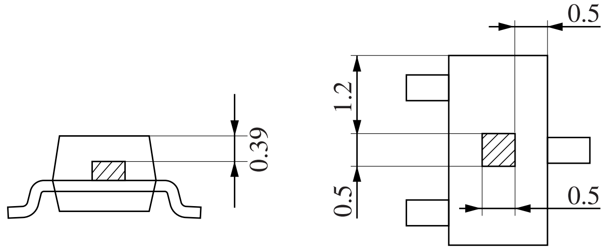
Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Operating magnetic flux density 1	B_{H-L}	V_{CC} = 3 V	—	—	6	mT
Operating magnetic flux density 2	B_{L-H}	V_{CC} = 3 V	0.5	—	—	mT
Hysteresis width	BW	V_{CC} = 3 V	—	1.2	—	mT
Output voltage	V_{OL}	V_{CC} = 3 V, I_O = 5 mA, B = 6 mT	—	0.1	0.3	V
Output current	I_{OH}	V_{CC} = 3 V, V_O = 3 V, B = 0.5 mT	—	—	10	µA
Supply current 1	I_{CCON}	V_{CC} = 3 V, B = 0.5 mT	—	2	—	mA
Supply current 2	I_{CCOFF}	V_{CC} = 3 V, B = 0.5 mT	—	3	—	µA
Supply current 3	I_{CCAVE}	V_{CC} = 3 V, B = 0.5 mT	—	10	15	µA

Note) 1. Symbol B_{H-L} stands for the operating magnetic flux density where its output level varies from high to low.
2. Symbol B_{L-H} stands for the operating magnetic flux density where its output level varies from low to high.
3. I_{CCON} is a consumption current when the magnetism detection system is on, and I_{CCOFF} is that when the magnetism detection system is off. One magnetism detection cycle is On = 200 µs and Off = 51 ms. I_{CCAVE} is an average consumption current.

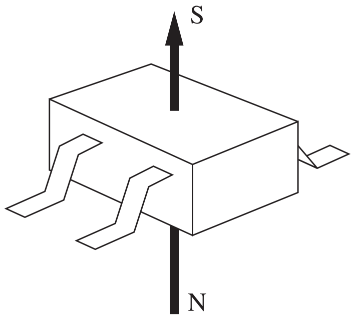
■ Technical Data

• Position of a Hall element (unit in mm)

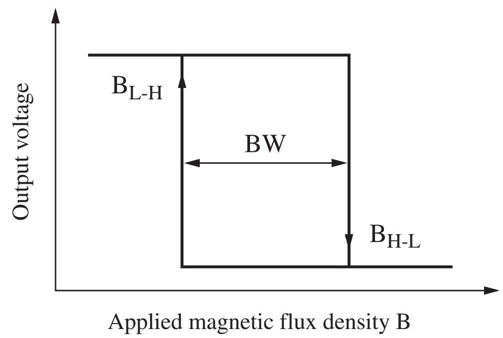
Distance from a package surface to sensor part: 0.39 mm (reference value)
A Hall element is placed on the shaded part in the figure.



• Magneto-electro conversion characteristics

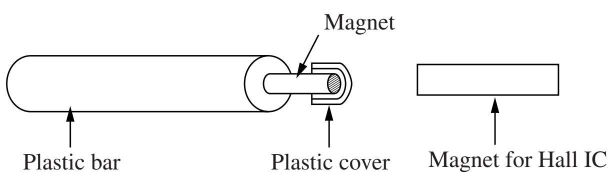


Direction of applied magnetic field



Operating magnetic flux density

• Simple polarity distinction method of mounting magnet to product incorporating Hall IC



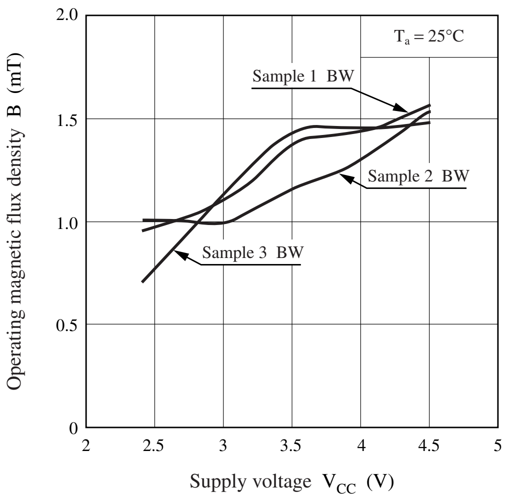
A magnet, which is used in pair with a Hall IC, can be mounted to a product incorporating a built-in Hall IC (e.g., a cellular phone) smoothly and correctly with a simple tool. The polarity of the magnet (hereafter referred to as Hall IC magnet) will be automatically discriminated.

This tool is a plastic bar, one end of which is attached with a small magnet (hereafter referred to as plastic bar magnet), as shown in the above illustration. The plastic bar magnet, the polarity of which is known, is secured on the bar with a plastic cover. When the plastic bar magnet is located close to the Hall IC magnet, the Hall IC magnet will be attracted to the plastic bar magnet. The contact side of the Hall IC magnet is different in polarity from that of the plastic bar magnet. As a matter of course, the polarity of the Hall IC magnet will be known then. The Hall IC magnet can be mounted to the appliance in this state. The attraction force of the plastic bar magnet is rather weak due to the plastic cover on it. Therefore, the plastic bar can be separated from the Hall IC magnet with ease after the Hall IC magnet is mounted properly.

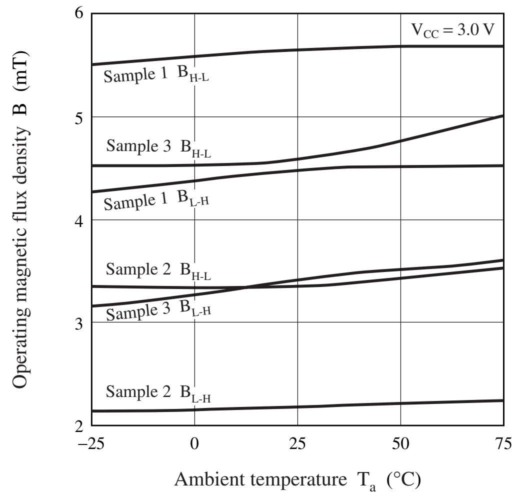
■ Technical Data (continued)

• Main characterisitcs

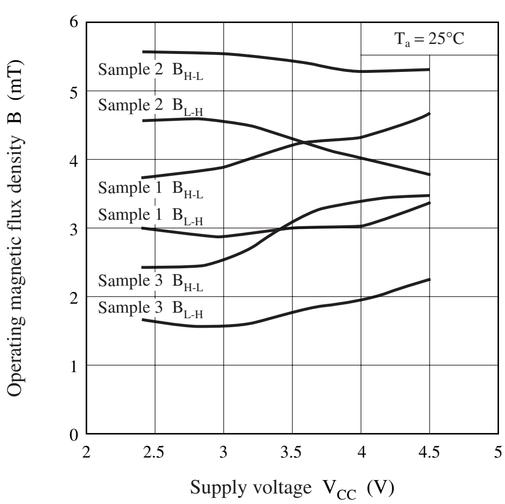
Operating magnetic flux density — Supply voltage



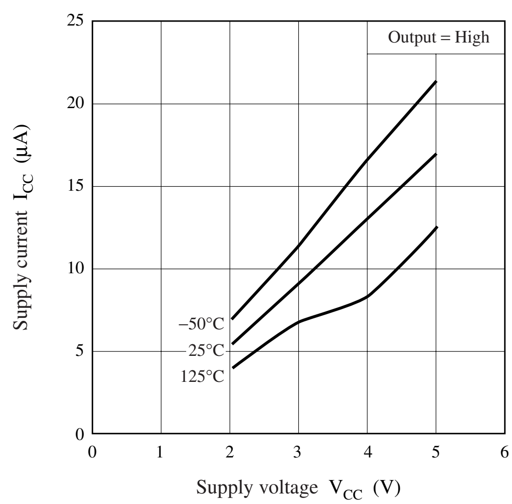
Operating magnetic flux density — Ambient temperature



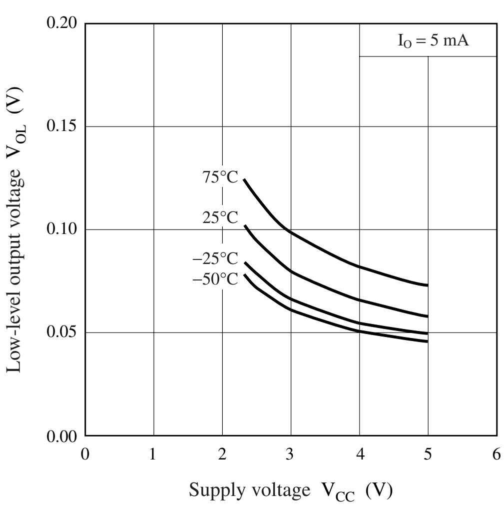
Operating magnetic flux density — Supply voltage



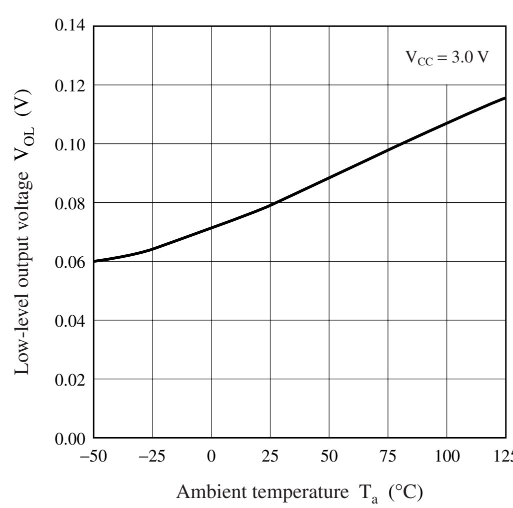
Average consumption current — Supply voltage



Low-level output voltage — Supply voltage

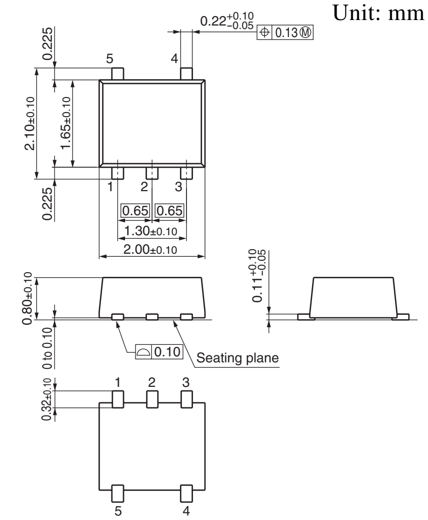


Low-level output voltage — Ambient temperature



AN48810B

Low current consumption, high sensitivity CMOS Hall IC One-way magnetic field operation



SMINI-5DA (Lead-free package)

■ Overview

The AN48810B is a Hall IC (a magnetic sensor) which has 2 times or more sensitivity and a low current consumption of about one three-hundredth compared with our conventional one.

In this Hall IC, a Hall element, a offset cancel circuit, an amplifier circuit, a sample and hold circuit, a Schmidt circuit, and output stage FET are integrated on a single chip housed in a small package by IC technique.

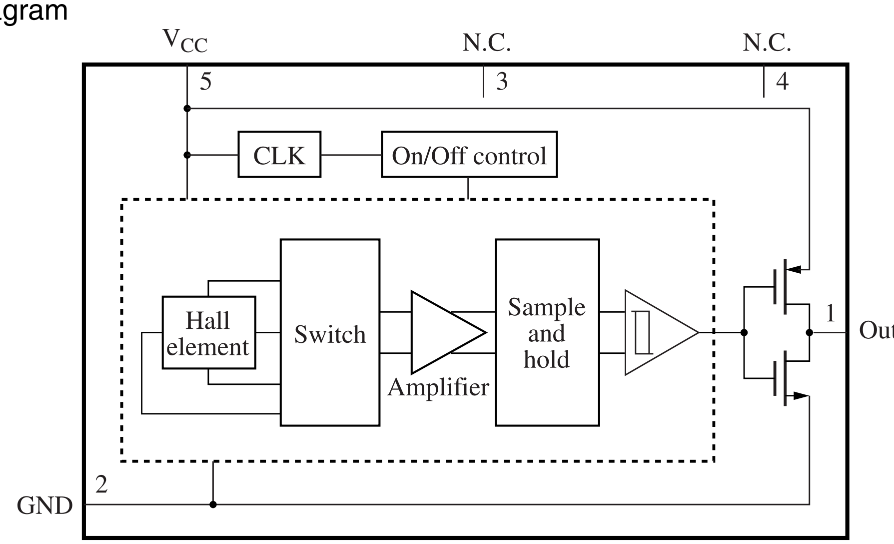
■ Features

- High sensitivity (6 mT max.) due to offset cancel circuit and a new sample and hold circuit
- Small current by using intermittent action
- Small package (SMD)
- CMOS inverter output

■ Applications

- Flip type cellular phone, digital video camera

■ Block Diagram



Note) The magnetism detection time should be longer than one intermittent action cycle (On = 200 µs and Off = 51 ms).

■ Pin Descriptions

Pin No.	Symbol	Description	Pin No.	Symbol	Description
1	Out	Output	4	N.C.	
2	GND	Ground	5	V_{CC}	Power supply
3	N.C.				

■ Absolute Maximum Ratings

Parameter	Symbol	Rating	Unit
Supply voltage	V_{CC}	5	V
	V_{OUT}	5	V
Output current	I_O	15	mA
Power dissipation	P_D	60	mW
Operating ambient temperature	T_{opr}	–20 to +75	°C
Storage temperature	T_{stg}	–55 to +125	°C

Note) 1. Except for the operating ambient temperature and storage temperature, all ratings are for T_a = 25°C.
2. The reverse insertion of this IC will cause its breakdown.
3. It will operate normally in several tens of ms after power on.
4. This IC is not suitable for car electrical equipment.

■ Recommended Operating Range

Parameter	Symbol	Range	Unit
Supply voltage	V_{CC}	2.5 to 3.5	V

■ Electrical Characteristics at T_a = 25°C

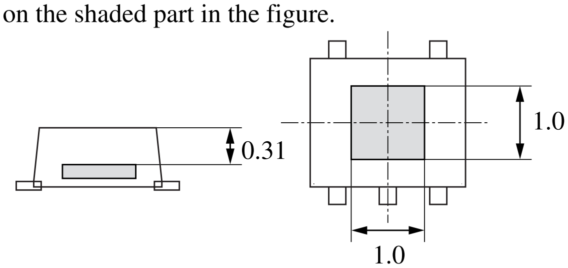
Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Operating magnetic flux density 1	B_{H-L}	V_{CC} = 3 V	—	—	6	mT
Operating magnetic flux density 2	B_{L-H}	V_{CC} = 3 V	0.5	—	—	mT
Hysteresis width	BW	V_{CC} = 3 V	—	1.2	—	mT
Output voltage 1	V_{OL}	V_{CC} = 3 V, I_O = 2 mA, B = 6 mT	—	0.1	0.3	V
Output voltage 2	V_{OH}	V_{CC} = 3 V, I_O = –2 mA, B = 0.5 mT	2.7	2.9	—	V
Supply current 1	I_{CCON}	V_{CC} = 3 V, B = 0.5 mT	—	2	—	mA
Supply current 2	I_{CCOFF}	V_{CC} = 3 V, B = 0.5 mT	—	3	—	µA
Supply current 3	I_{CCAVE}	V_{CC} = 3 V, B = 0.5 mT	—	10	15	µA

Note) 1. Symbol B_{H-L} stands for the operating magnetic flux density where its output level varies from high to low.
2. Symbol B_{L-H} stands for the operating magnetic flux density where its output level varies from low to high.
3. I_{CCON} is a consumption current when the magnetism detection system is on, and I_{CCOFF} is that when the magnetism detection system is off. One magnetism detection cycle is On = 200 µs and Off = 51 ms. I_{CCAVE} is an average consumption current.

■ Technical Data

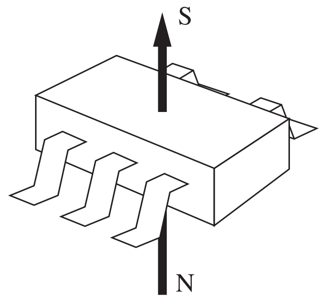
• Position of a Hall element (unit in mm)

Distance from a package surface to sensor part: 0.31 mm (reference value)
A Hall element is placed on the shaded part in the figure.

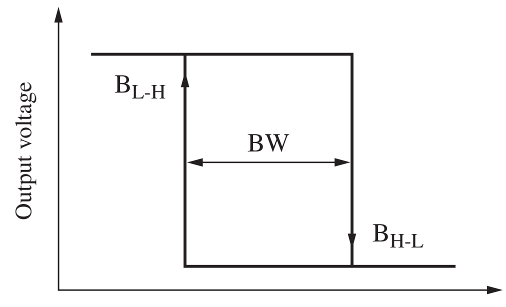


■ Technical Data (continued)

• Magneto-electro conversion characteristics

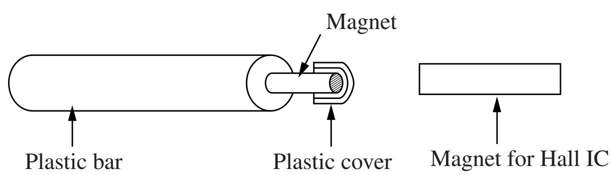


Direction of applied magnetic field



Operating magnetic flux density

• Simple polarity distinction method of mounting magnet to product incorporating Hall IC

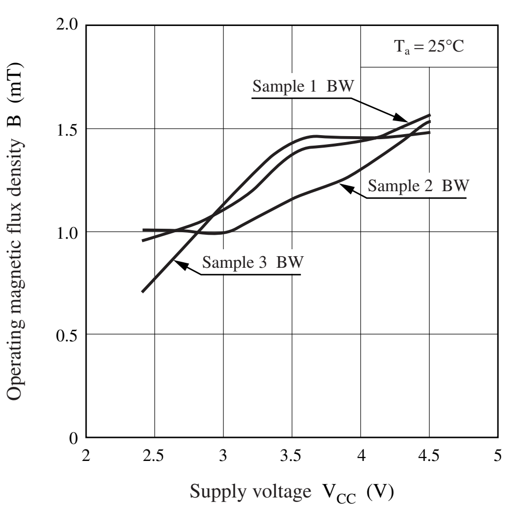


A magnet, which is used in pair with a Hall IC, can be mounted to a product incorporating a built-in Hall IC (e.g., a cellular phone) smoothly and correctly with a simple tool. The polarity of the magnet (hereafter referred to as Hall IC magnet) will be automatically discriminated.

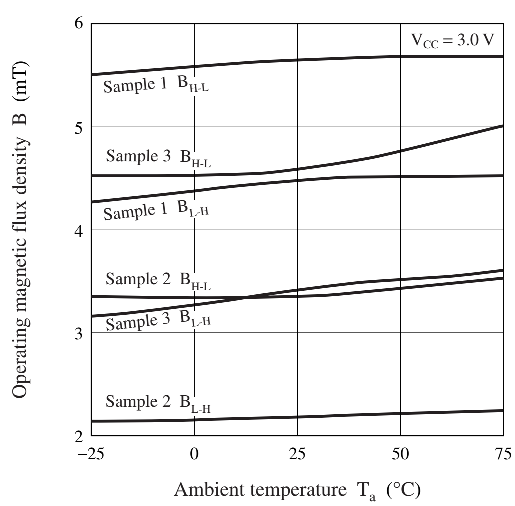
This tool is a plastic bar, one end of which is attached with a small magnet (hereafter referred to as plastic bar magnet), as shown in the above illustration. The plastic bar magnet, the polarity of which is known, is secured on the bar with a plastic cover. When the plastic bar magnet is located close to the Hall IC magnet, the Hall IC magnet will be attracted to the plastic bar magnet. The contact side of the Hall IC magnet is different in polarity from that of the plastic bar magnet. As a matter of course, the polarity of the Hall IC magnet will be known then. The Hall IC magnet can be mounted to the appliance in this state. The attraction force of the plastic bar magnet is rather weak due to the plastic cover on it. Therefore, the plastic bar can be separated from the Hall IC magnet with ease after the Hall IC magnet is mounted properly.

• Main characterisitcs

Operating magnetic flux density — Supply voltage



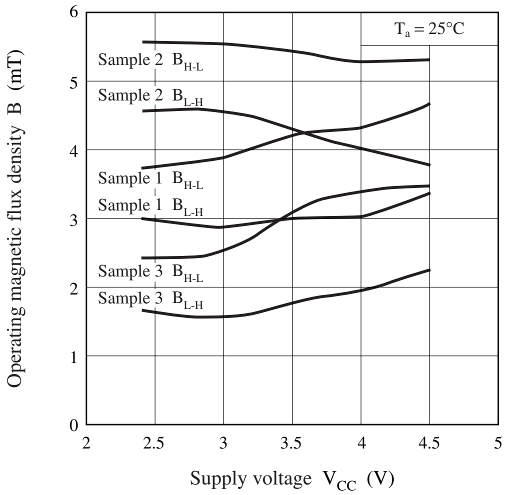
Operating magnetic flux density — Ambient temperature



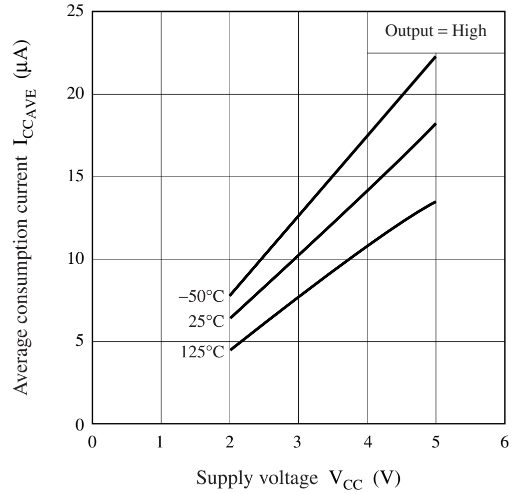
■ Technical Data (continued)

- Main characterisitcs

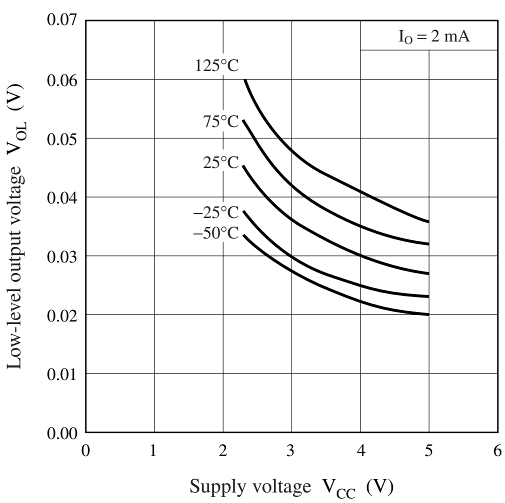
Operating magnetic flux density — Supply voltage



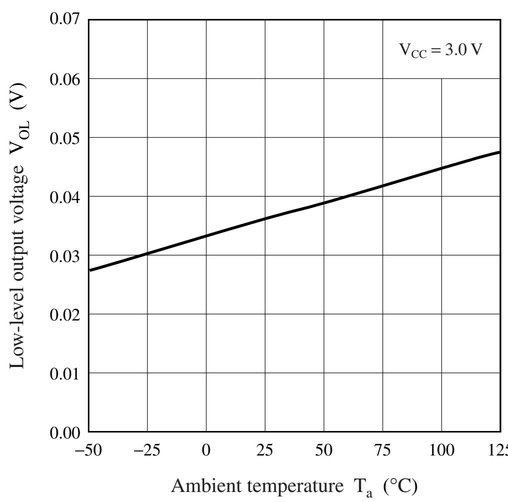
Average consumption current — Supply voltage



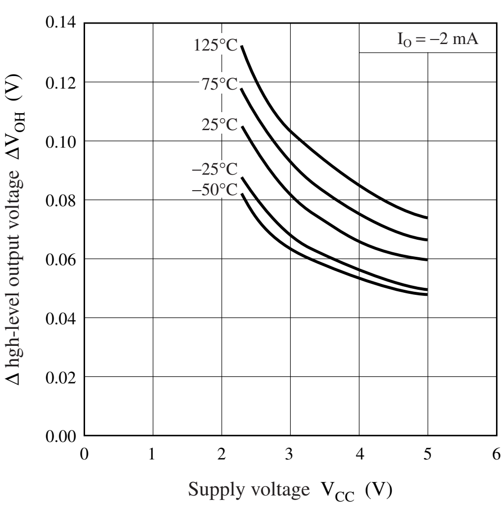
Low-level output voltage — Supply voltage



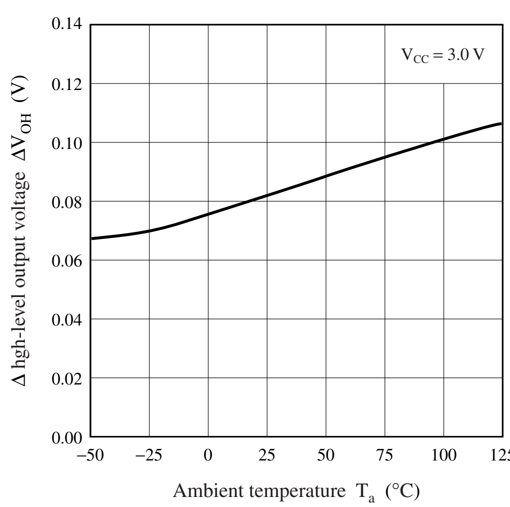
Low-level output voltage — Ambient temperature



Δ high-level output voltage — Supply voltage



Δ high-level output voltage — Ambient temperature



DN8796MS

3 V operation Hall IC
Alternating magnetic field operation

■ Overview

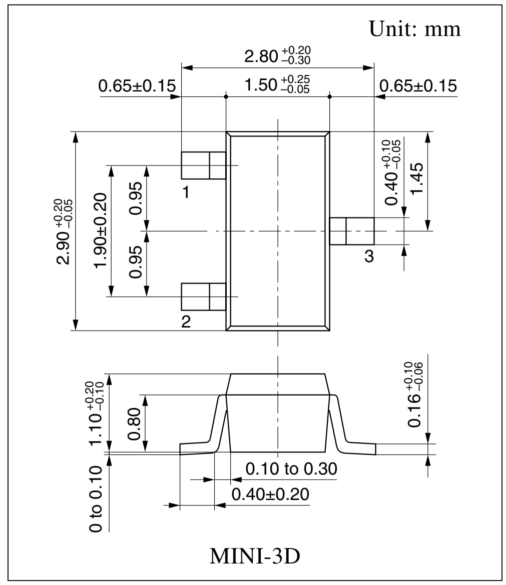
The DN8796MS is a 3 V operation Hall IC which includes a Hall element, amplifier circuit, Schmidt circuit, stabilized power supply and temperature compensation circuit which are integrated on a single chip with a fine patterning technology. The magnetic input signal is outputted by being converted to high or low. We have improved the conventional circuit to realize a stable operation covering from low to high supply voltage and from low to high temperature.

■ Features

- Wide operating supply voltage range (V_{CC} = 2.7 V to 14.4 V)
- Wide operating ambient temperature (–40°C to +85°C)
- Package: Mini type (3-pin type) (1.1 mm thick: Same as a standard transistor)
- Eqipped with an output pull-up resistor (typical 56 kΩ)

■ Applications

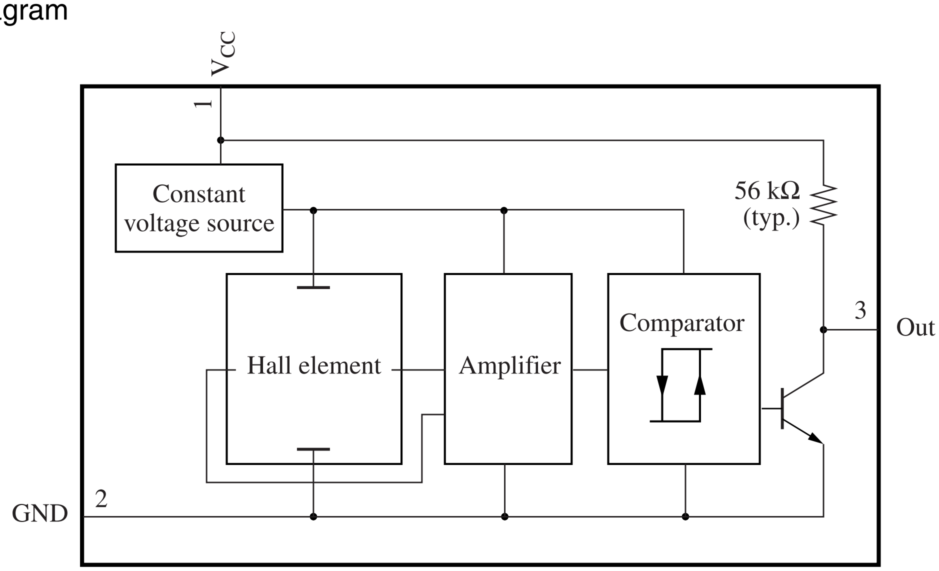
- DC brushless motor, fan motor, rotation sensor, detection of cover open/close (example for a cellular phone), position sensor



MINI-3D

Note) The package of this product will be changed to lead-free type (MINI-3DA). See the new package dimensions section later of this datasheet.

■ Block Diagram



■ Pin Descriptions

Pin No.	Symbol	Description
1	Out	Output pin
2	V_{CC}	Supply voltage pin
3	GND	Ground pin

■ Absolute Maximum Ratings

Parameter	Symbol	Rating	Unit
Supply voltage	V_{CC}	18	V
	V_{OUT}	18	
Supply current	I_{CC}	—	mA
Power dissipation	P_D	120	mW
Operating ambient temperature	T_{opr}	−40 to +85	°C
Storage temperature	T_{stg}	−55 to +125	°C

Note) 1. Except for the operating ambient temperature and storage temperature, all ratings are for T_a = 25°C.
2. The reverse insertion of this IC will cause its breakdown.
3. It will operate normally in several tens of ms after power on.
4. This IC is not suitable for car electrical equipment.

■ Recommended Operating Range

Parameter	Symbol	Range	Unit
Supply voltage	V_{CC}	2.7 to 14.4	V

■ Electrical Characteristics at T_a = 25°C

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Operating magnetic flux density 1	B_{H-L}	V_{CC} = 3 V	−18	—	—	mT
Operating magnetic flux density 2	B_{L-H}	V_{CC} = 3 V	—	—	18	mT
Hysteresis width	BW	V_{CC} = 3 V	4	8	12	mT
Output voltage 1	V_{OL1}	V_{CC} = 14.4 V, I_O = 5 mA, B = −18 mT	—	0.07	0.30	V
Output voltage 2	V_{OL2}	V_{CC} = 2.7 V, I_O = 5 mA, B = −18 mT	—	0.07	0.30	V
Output voltage 3	V_{OH1}	V_{CC} = 14.4 V, I_O = −20 μA, B = 18 mT	12.8	13.3	13.8	V
Output voltage 4	V_{OH2}	V_{CC} = 2.7 V, I_O = −20 μA, B = 18 mT	1.05	1.55	2.05	V
Output short-circuited current	$-I_{OS}$	V_{CC} = 14.4 V, B = 18 mT, V_O = 0 V	0.19	0.27	0.39	mA
Supply current 1	I_{CC1}	V_{CC} = 14.4 V, B = 18 mT	1.0	3.4	6.0	mA
Supply current 2	I_{CC2}	V_{CC} = 2.7 V, B = 18 mT	1.0	2.5	6.0	mA

Note) 1. Symbol B_{H-L} stands for the operating magnetic flux density where its output level varies from high to low.
2. Symbol B_{L-H} stands for the operating magnetic flux density where its output level varies from low to high.
3. The variation of operating magnetic flux density does not depend on supply voltage due to its built-in stabilized power source. (V_{CC} should be confined to the range of 2.7 V to 14.4 V.)
4. A supply current changes by maximum 1 mA when its output level varies from high to low.

DN8797MS

3 V operation Hall IC
One-way magnetic field operation

■ Overview

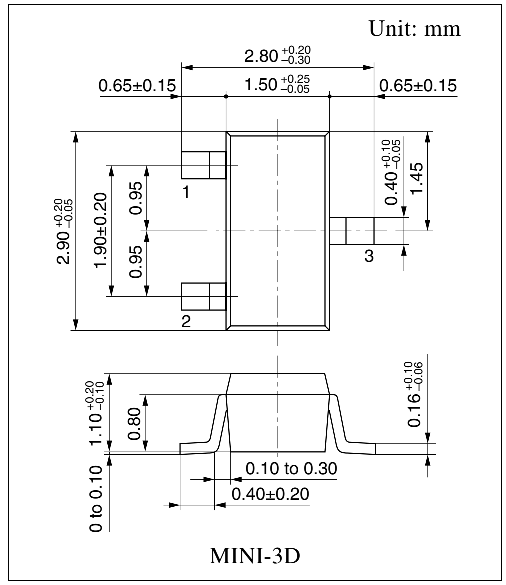
The DN8797MS is a 3 V operation Hall IC which includes a Hall element, amplifier circuit, Schmidt circuit, stabilized power supply and temperature compensation circuit which are integrated on a single chip with a fine patterning technology. The magnetic input signal is outputted by being converted to high or low. We have improved the conventional circuit to realize a stable operation covering from low to high supply voltage and from low to high temperature.

■ Features

- Wide operating supply voltage range (V_{CC} = 2.7 V to 14.4 V)
- Wide operating ambient temperature (–40°C to +85°C)
- Package: Mini type (3-pin type) (1.1 mm thick: Same as a standard transistor)
- Eqipped with an output pull-up resistor (typical 56 kΩ)

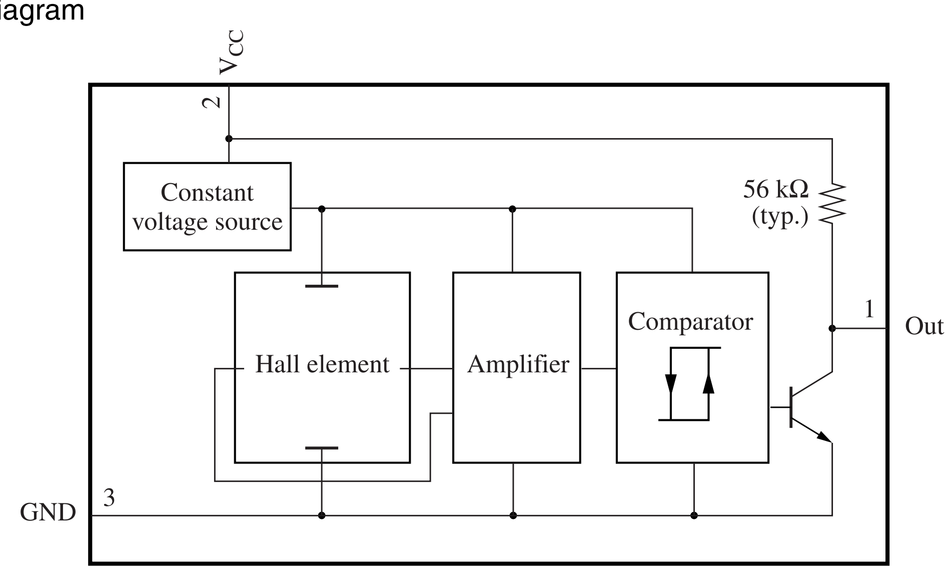
■ Applications

- DC brushless motor, fan motor, rotation sensor, detection of cover open/close (example for a cellular phone), position sensor



Note) The package of this product will be changed to lead-free type (MINI-3DA). See the new package dimensions section later of this datasheet.

■ Block Diagram



■ Pin Descriptions

Pin No.	Symbol	Description
1	Out	Output pin
2	V_{CC}	Supply voltage pin
3	GND	Ground pin

■ Absolute Maximum Ratings

Parameter	Symbol	Rating	Unit
Supply voltage	V_{CC}	18	V
	V_{OUT}	18	
Supply current	I_{CC}	—	mA
Power dissipation	P_D	120	mW
Operating ambient temperature	T_{opr}	–20 to +85	°C
Storage temperature	T_{stg}	–55 to +125	°C

Note) 1. Except for the operating ambient temperature and storage temperature, all ratings are for T_a = 25°C.
2. The reverse insertion of this IC will cause its breakdown.
3. It will operate normally in several tens of ms after power on.
4. This IC is not suitable for car electrical equipment.

■ Recommended Operating Range

Parameter	Symbol	Range	Unit
Supply voltage	V_{CC}	2.7 to 14.4	V

■ Electrical Characteristics at T_a = 25°C

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Operating magnetic flux density 1	B_{H-L}	V_{CC} = 3 V	–20	—	—	mT
Operating magnetic flux density 2	B_{L-H}	V_{CC} = 3 V	—	—	–3	mT
Hysteresis width	BW	V_{CC} = 3 V	0.2	1.5	4	mT
Output voltage 1	V_{OL1}	V_{CC} = 14.4 V, I_O = 5 mA, B = –22 mT	—	0.07	0.30	V
Output voltage 2	V_{OL2}	V_{CC} = 2.7 V, I_O = 5 mA, B = –22 mT	—	0.07	0.30	V
Output voltage 3	V_{OH1}	V_{CC} = 14.4 V, I_O = –20 µA, B = –3 mT	12.8	13.3	13.8	V
Output voltage 4	V_{OH2}	V_{CC} = 2.7 V, I_O = –20 µA, B = –3 mT	1.05	1.55	2.05	V
Output short-circuited current	$-I_{OS}$	V_{CC} = 14.4 V, B = –3 mT, V_O = 0 V	0.19	0.27	0.39	mA
Supply current 1	I_{CC1}	V_{CC} = 14.4 V, B = –3 mT	1.0	3.4	6.0	mA
Supply current 2	I_{CC2}	V_{CC} = 2.7 V, B = –3 mT	1.0	2.5	6.0	mA

Note) 1. Symbol B_{H-L} stands for the operating magnetic flux density where its output level varies from high to low.
2. Symbol B_{L-H} stands for the operating magnetic flux density where its output level varies from low to high.
3. The variation of operating magnetic flux density does not depend on supply voltage due to its built-in stabilized power source. (V_{CC} should be confined to the range of 2.7 V to 14.4 V.)
4. A supply current changes by maximum 1 mA when its output level varies from high to low.

DN8798MS

3 V operation Hall IC
Alternating magnetic field operation

■ Overview

The DN8798MS is a 3 V operation Hall IC which includes a Hall element, amplifier circuit, Schmidt circuit, stabilized power supply and temperature compensation circuit which are integrated on a single chip with a fine patterning technology. The magnetic input signal is outputted by being converted to high or low. We have improved the conventional circuit to realize a stable operation covering from low to high supply voltage and from low to high temperature.

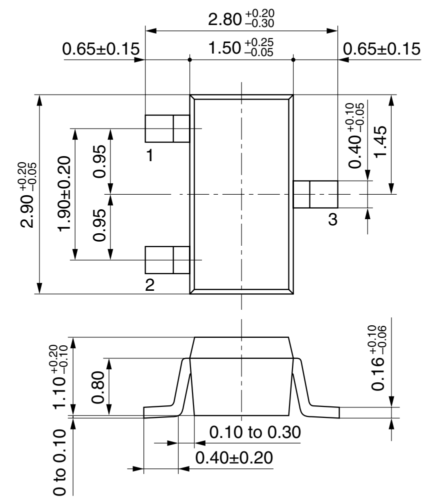
■ Features

- Wide operating supply voltage range (V_{CC} = 2.7 V to 14.4 V)
- Wide operating ambient temperature (−40°C to +85°C)
- Package: Mini type (3-pin type) (1.1 mm thick: Same as a standard transistor)
- Open collector output

■ Applications

- DC brushless motor, fan motor, rotation sensor, detection of cover open/close (example for a cellular phone), position sensor

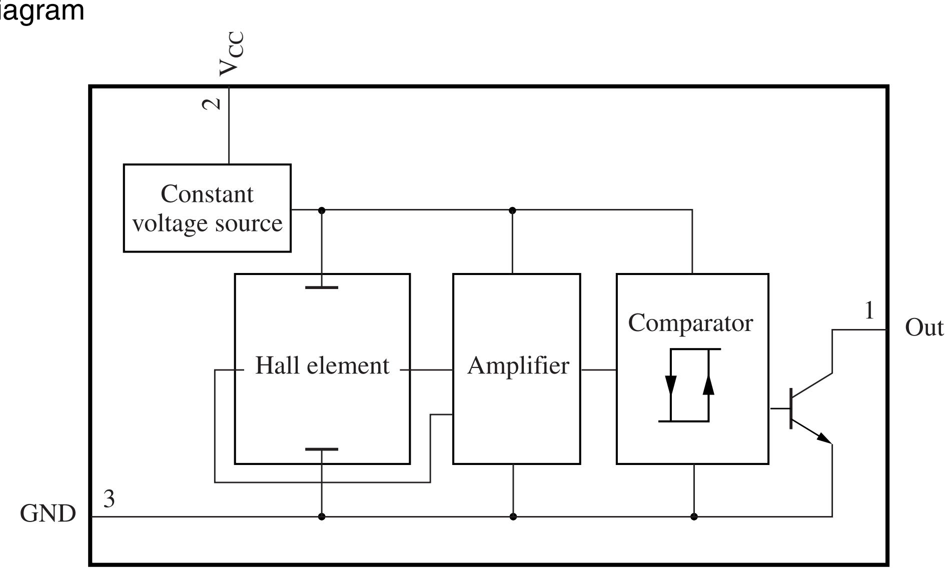
Unit: mm



MINI-3D

Note) The package of this product will be changed to lead-free type (MINI-3DA). See the new package dimensions section later of this datasheet.

■ Block Diagram



■ Pin Descriptions

Pin No.	Symbol	Description
1	Out	Output pin
2	V_{CC}	Supply voltage pin
3	GND	Ground pin

■ Absolute Maximum Ratings

Parameter	Symbol	Rating	Unit
Supply voltage	V_{CC}	18	V
	V_{OUT}	18	
Supply current	I_{CC}	—	mA
Power dissipation	P_D	120	mW
Operating ambient temperature	T_{opr}	–40 to +85	°C
Storage temperature	T_{stg}	–55 to +125	°C

Note) 1. Except for the operating ambient temperature and storage temperature, all ratings are for T_a = 25°C.
2. The reverse insertion of this IC will cause its breakdown.
3. It will operate normally in several tens of ms after power on.
4. This IC is not suitable for car electrical equipment.

■ Recommended Operating Range

Parameter	Symbol	Range	Unit
Supply voltage	V_{CC}	2.7 to 14.4	V

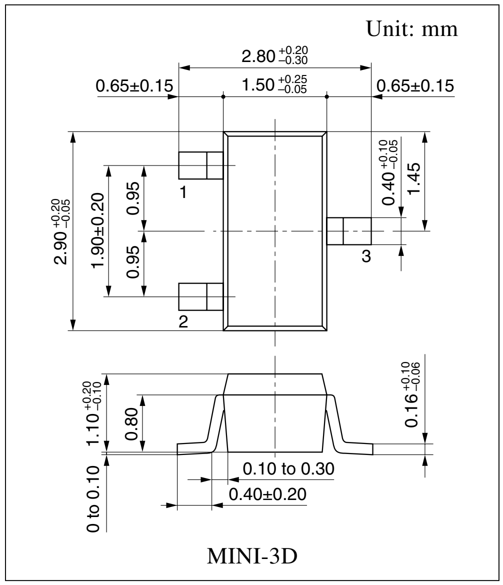
■ Electrical Characteristics at T_a = 25°C

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Operating magnetic flux density 1	B_{H-L}	V_{CC} = 3 V	–15	—	—	mT
Operating magnetic flux density 2	B_{L-H}	V_{CC} = 3 V	—	—	15	mT
Hysteresis width	BW	V_{CC} = 3 V	4	8	12	mT
Output voltage 1	V_{OL1}	V_{CC} = 14.4 V, I_O = 5 mA, B = –15 mT	—	0.07	0.30	V
Output voltage 2	V_{OL2}	V_{CC} = 2.7 V, I_O = 5 mA, B = –15 mT	—	0.07	0.30	V
Output current	I_{OH}	V_{CC} = 2.7 V to 14.4 V V_O = 14.4 V, B = 15 mT	—	—	10	μA
Supply current 1	I_{CC1}	V_{CC} = 14.4 V, B = 15 mT	1.0	3.4	6.0	mA
Supply current 2	I_{CC2}	V_{CC} = 2.7 V, B = 15 mT	1.0	2.5	6.0	mA

Note) 1. Symbol B_{H-L} stands for the operating magnetic flux density where its output level varies from high to low.
2. Symbol B_{L-H} stands for the operating magnetic flux density where its output level varies from low to high.
3. The variation of operating magnetic flux density does not depend on supply voltage due to its built-in stabilized power source. (V_{CC} should be confined to the range of 2.7 V to 14.4 V.)
4. A supply current changes by maximum 1 mA when its output level varies from high to low.

DN8799MS

3 V operation Hall IC
One-way magnetic field operation



Note) The package of this product will be changed to lead-free type (MINI-3DA). See the new package dimensions section later of this datasheet.

■ Overview

The DN8799MS is a 3 V operation Hall IC which includes a Hall element, amplifier circuit, Schmidt circuit, stabilized power supply and temperature compensation circuit which are integrated on a single chip with a fine patterning technology. The magnetic input signal is outputted by being converted to high or low. We have improved the conventional circuit to realize a stable operation covering from low to high supply voltage and from low to high temperature.

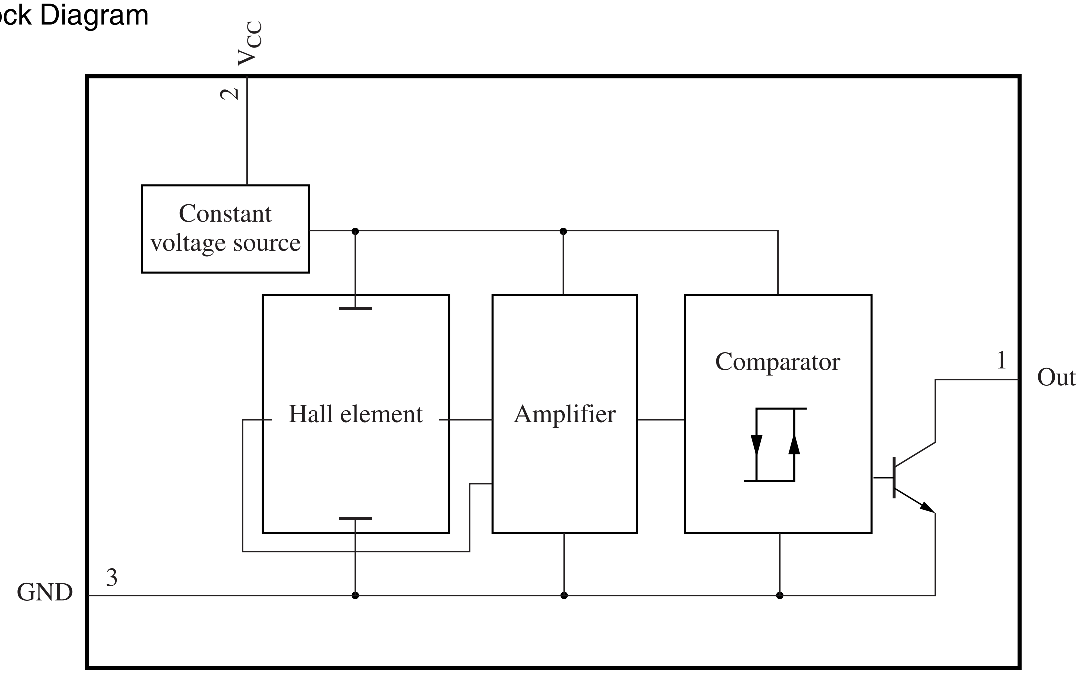
■ Features

- Wide operating supply voltage range (V_{CC} = 2.7 V to 14.4 V)
- Wide operating ambient temperature (−40°C to +85°C)
- Package: Mini type (3-pin type) (1.1 mm thick: Same as a standard transistor)
- Open collector output

■ Applications

- Cellular phone (detection of cover open/close), position sensor

■ Block Diagram



■ Pin Descriptions

Pin No.	Symbol	Description
1	Out	Output pin
2	V_{CC}	Supply voltage pin
3	GND	Ground pin

■ Absolute Maximum Ratings

Parameter	Symbol	Rating	Unit
Supply voltage	V_{CC}	18	V
	V_{OUT}	18	
Supply current	I_{CC}	—	mA
Power dissipation	P_D	120	mW
Operating ambient temperature	T_{opr}	–40 to +85	°C
Storage temperature	T_{stg}	–55 to +125	°C

Note) 1. Except for the operating ambient temperature and storage temperature, all ratings are for T_a = 25°C.
2. The reverse insertion of this IC will cause its breakdown.
3. It will operate normally in several tens of ms after power on.
4. This IC is not suitable for car electrical equipment.

■ Recommended Operating Range

Parameter	Symbol	Range	Unit
Supply voltage	V_{CC}	2.7 to 14.4	V

■ Electrical Characteristics at T_a = 25°C

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Operating magnetic flux density 1 *1	B_{H-L}	V_{CC} = 3 V	–20	—	—	mT
Operating magnetic flux density 2	B_{L-H}	V_{CC} = 3 V	—	—	–3	mT
Hysteresis width	BW	V_{CC} = 3 V	0.2	1.5	4.0	mT
Output voltage 1	V_{OL1}	V_{CC} = 14.4 V, I_O = 5 mA, B = –20 mT	—	0.07	0.30	V
Output voltage 2	V_{OL2}	V_{CC} = 2.7 V, I_O = 5 mA, B = –20 mT	—	0.07	0.30	V
Output current	I_{OH}	V_{CC} = 2.7 V to 14.4 V V_O = 14.4 V, B = –3 mT	—	—	10	µA
Supply current 1	I_{CC1}	V_{CC} = 14.4 V, B = –3 mT	1.0	3.4	6.0	mA
Supply current 2	I_{CC2}	V_{CC} = 2.7 V, B = –3 mT	1.0	2.5	6.0	mA

Note) 1. Symbol B_{H-L} stands for the operating magnetic flux density where its output level varies from high to low.
2. Symbol B_{L-H} stands for the operating magnetic flux density where its output level varies from low to high.
3. The variation of operating magnetic flux density does not depend on supply voltage due to its built-in stabilized power source. (V_{CC} should be confined to the range of 2.7 V to 14.4 V.)
4. A supply current changes by maximum 1 mA when its output level varies from high to low.
5. ∗1: Classified by B_{H-L} as listed right:

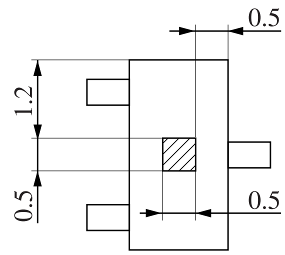
Rank	A
B_{H-L} (mT)	≥ –15

■ Technical Data (DN8796MS/DN8797MS/DN8798MS/DN8799MS)

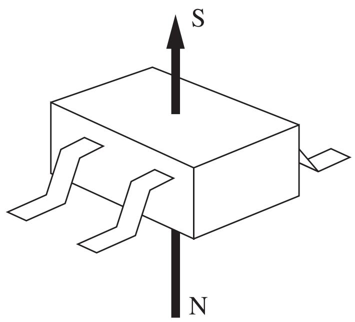
• Position of a Hall element (unit in mm)

Distance from a package surface to sensor part: 0.71 mm

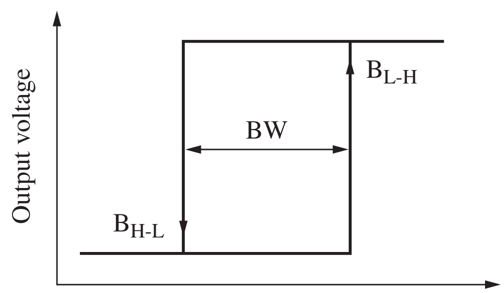
A Hall element is placed on the shaded part in the figure.



• Magneto-electro conversion characteristics



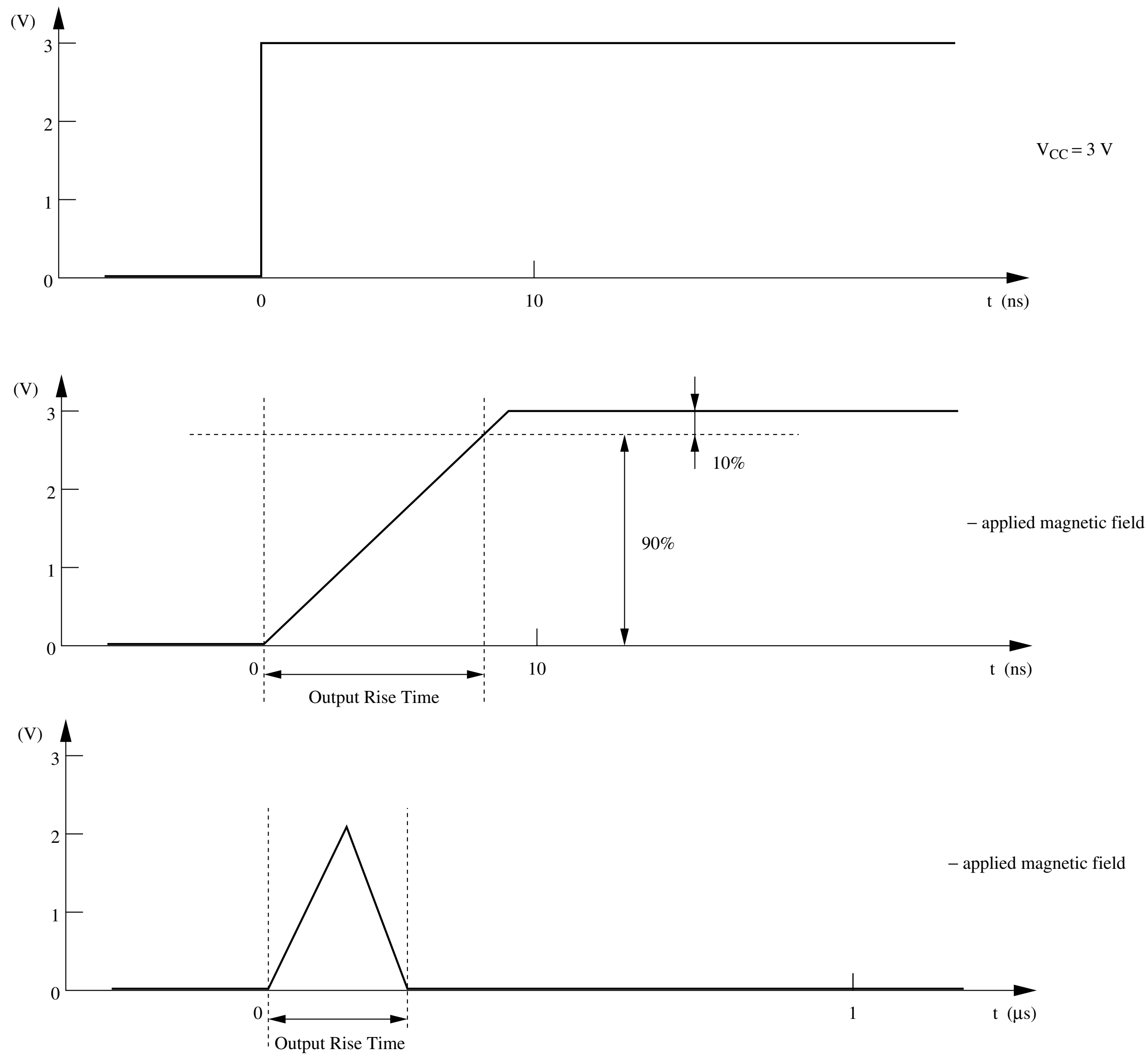
Direction of applied magnetic field



Applied magnetic flux density B

■ Technical Data (DN8796MS/DN8797MS/DN8798MS/DN8799MS)(continued)

• Output Rise Time

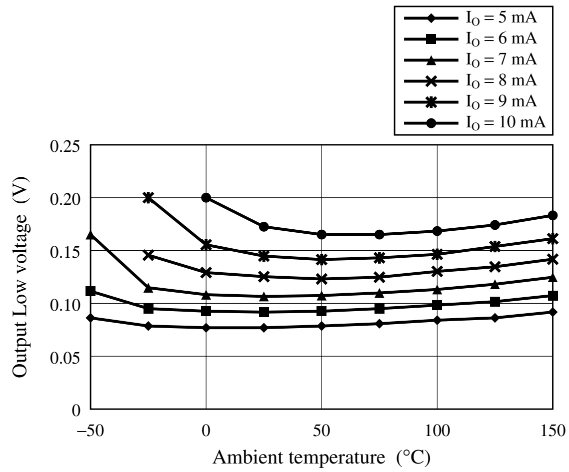


V_{CC} = 3.0 V, Pull-Up-R. = 56 kΩ

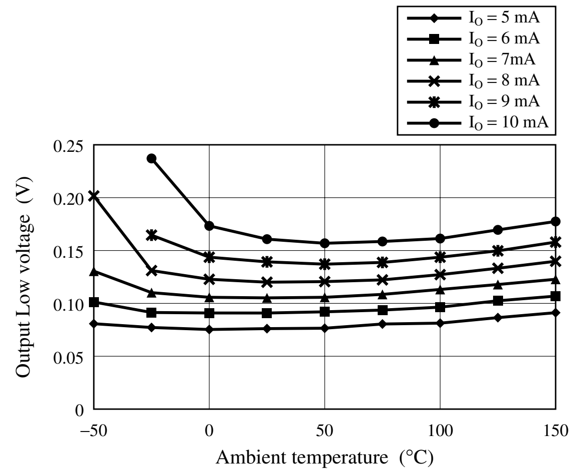
Output Rise Time	Sample. 1	Sample. 2	Sample. 3	Sample. 4	Sample. 5	Average
− aooliedmagnetic field (μs)	8.98	7.72	9.18	8.06	8.78	8.74
+ aooliedmagnetic field (ns)	292	318	356	280	320	313

■ Main characterisitcs (DN8796MS/DN8797MS/DN8798MS/DN8799MS)

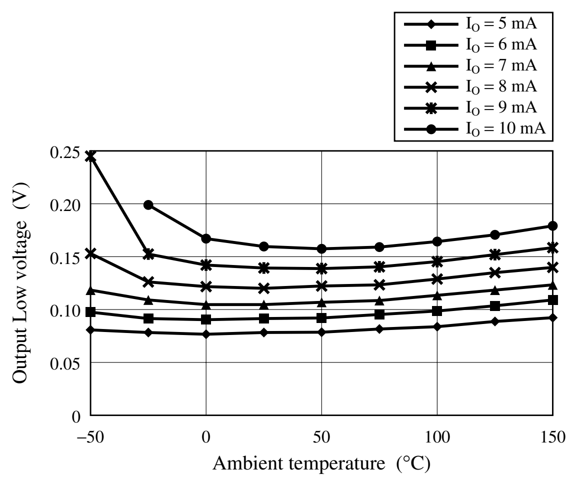
Output low voltage — Ambient temperature (V_{CC} = 2.7 V)



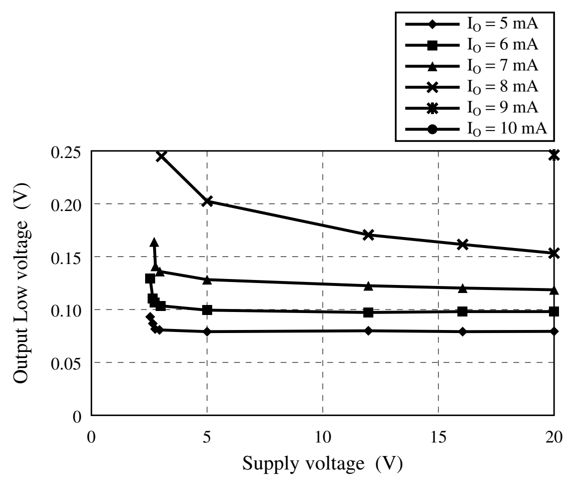
Output low voltage — Ambient temperature (V_{CC} = 5.0 V)



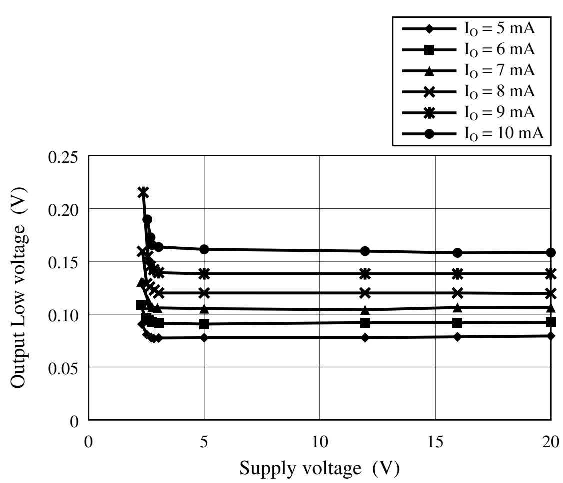
Output low voltage — Ambient temperature (V_{CC} = 20 V)



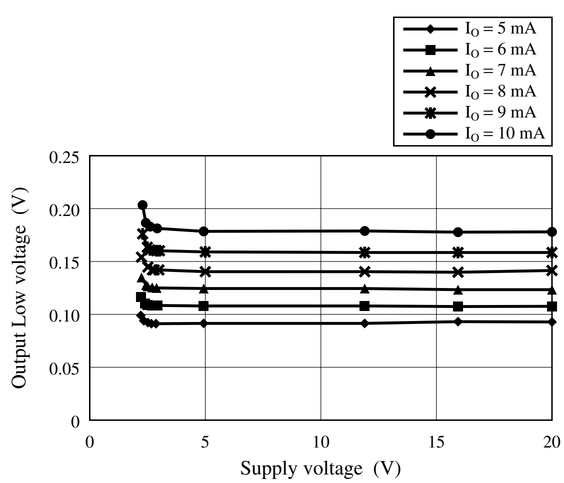
Output low voltage — Supply voltage (Temp. = –50°C)



Output low voltage — Supply voltage (Temp. = 25°C)

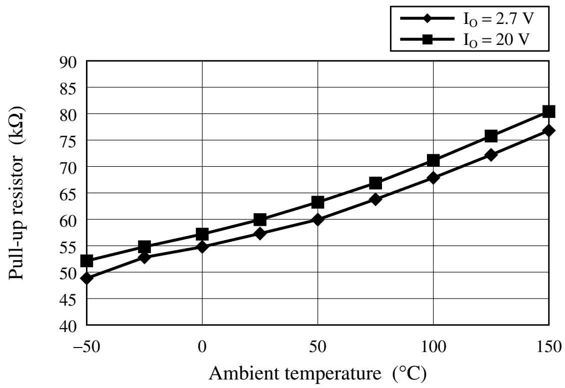


Output low voltage — Supply voltage (Temp. = 150°C)

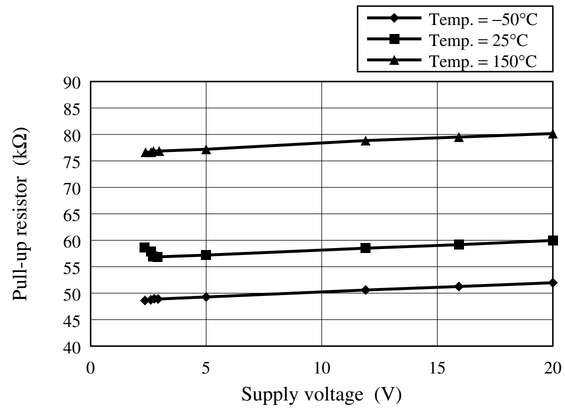


■ Main characterisitcs (DN8796MS/DN8797MS/DN8798MS/DN8799MS)(continued)

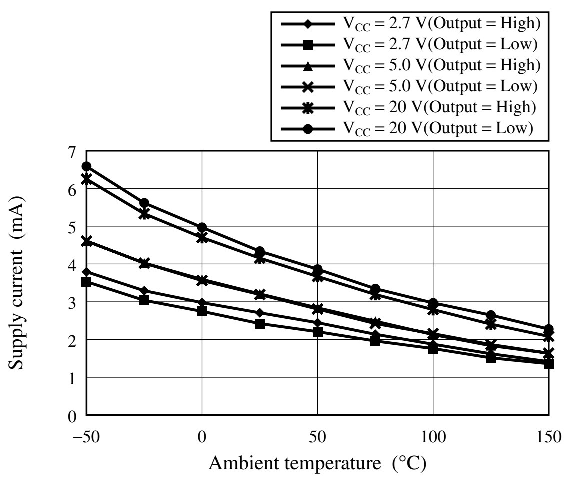
Pull-up resistor — Ambient temperature



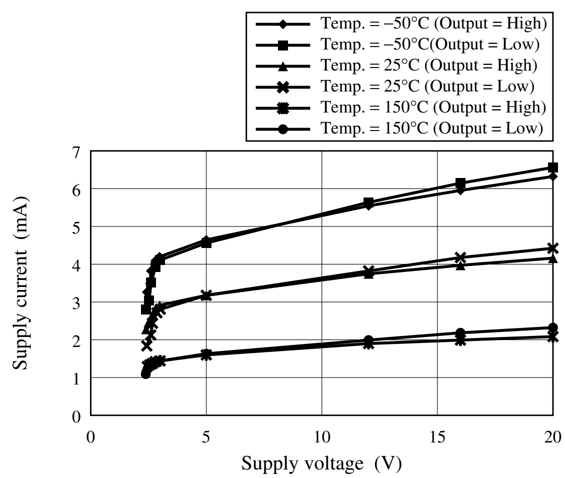
Pull-up resistor — Supply voltage



Supply current — Ambient temperature

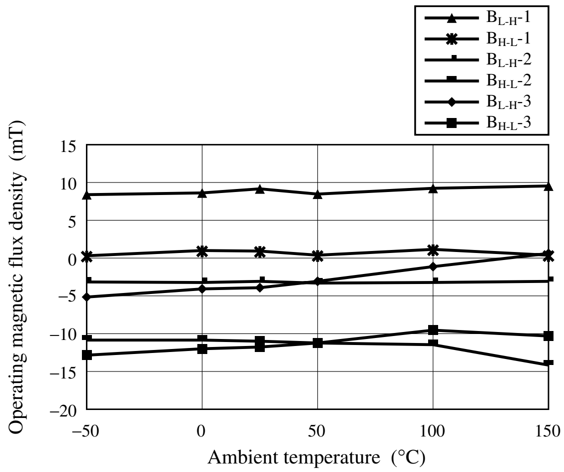


Supply current — Supply voltage

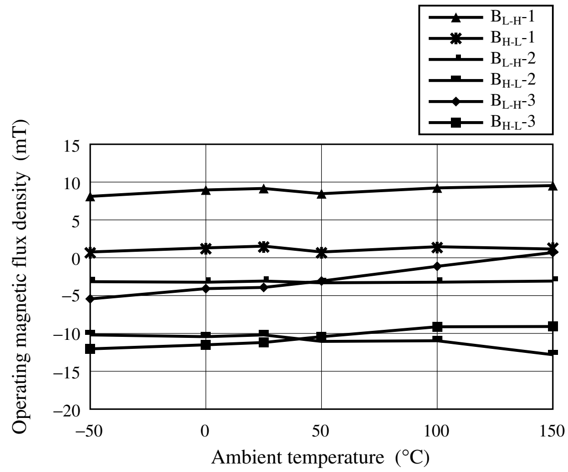


■ Main characterisitcs (DN8796MS/DN8798MS) (continued)

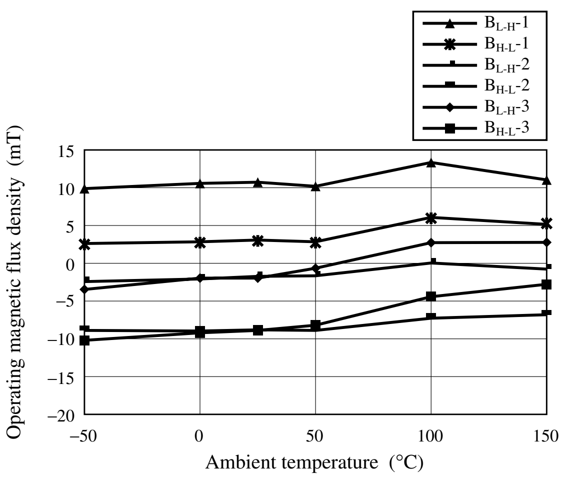
Operating magnetic flux density — Ambient temperature (V_{CC} = 2.7 V)



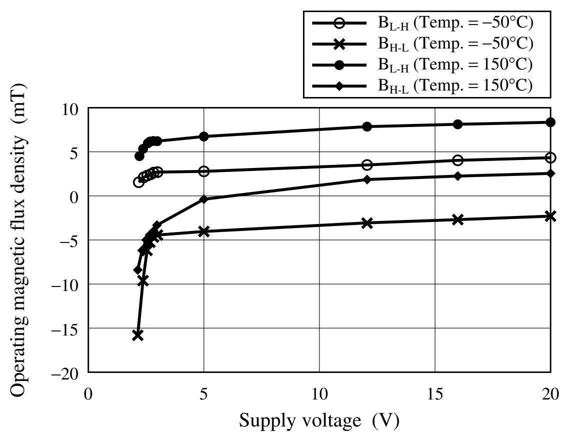
Operating magnetic flux density — Ambient temperature (V_{CC} = 3.0 V)



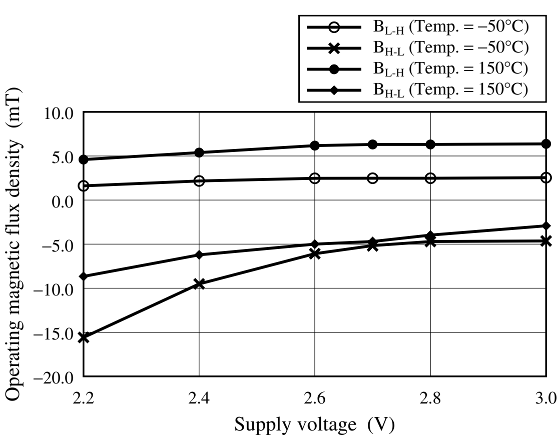
Operating magnetic flux density — Ambient temperature (V_{CC} = 20 V)



Operating magnetic flux density — Supply voltage

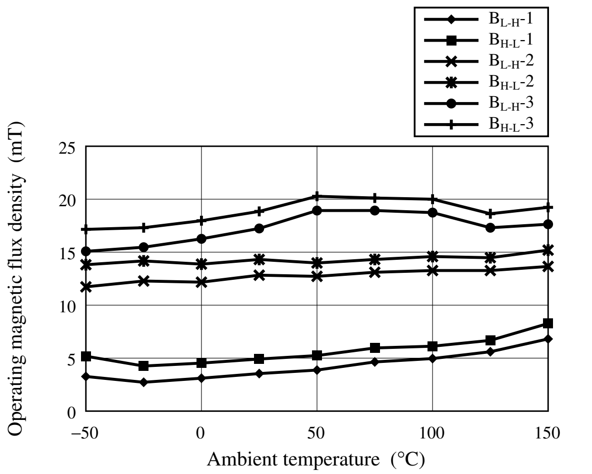


Operating magnetic flux density — Supply voltage

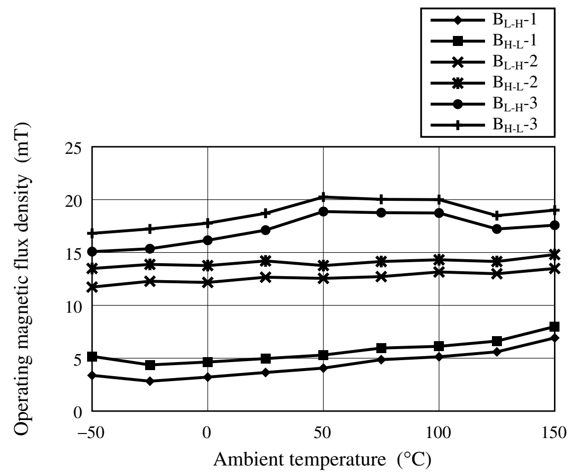


■ Main characterisitcs (DN8797MS/DN8799MS)

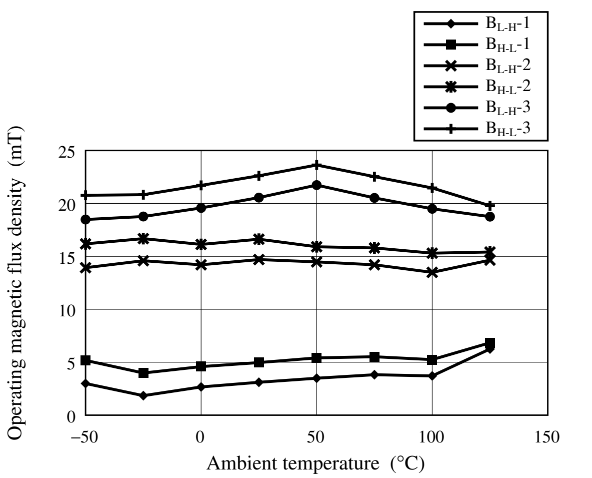
Operating magnetic flux density — Ambient temperature (V_{CC} = 2.7 V)



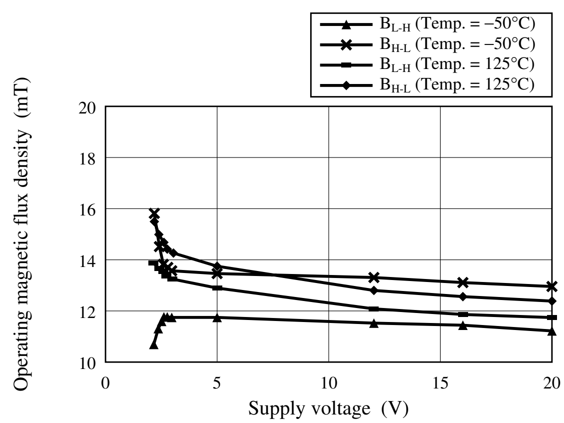
Operating magnetic flux density — Ambient temperature (V_{CC} = 3.0 V)



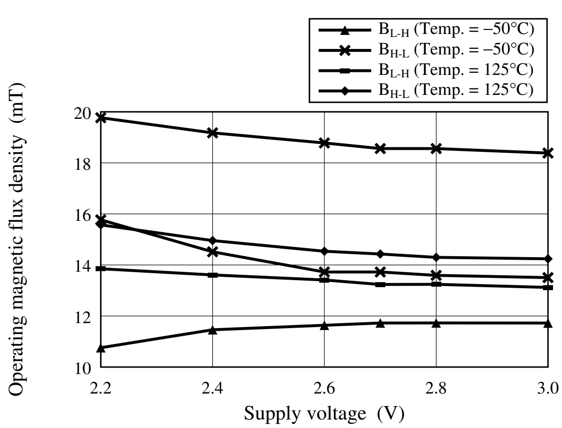
Operating magnetic flux density — Ambient temperature (V_{CC} = 20 V)



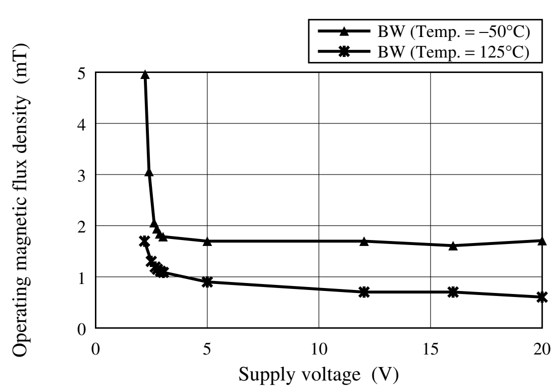
Operating magnetic flux density — Supply voltage



Operating magnetic flux density — Supply voltage

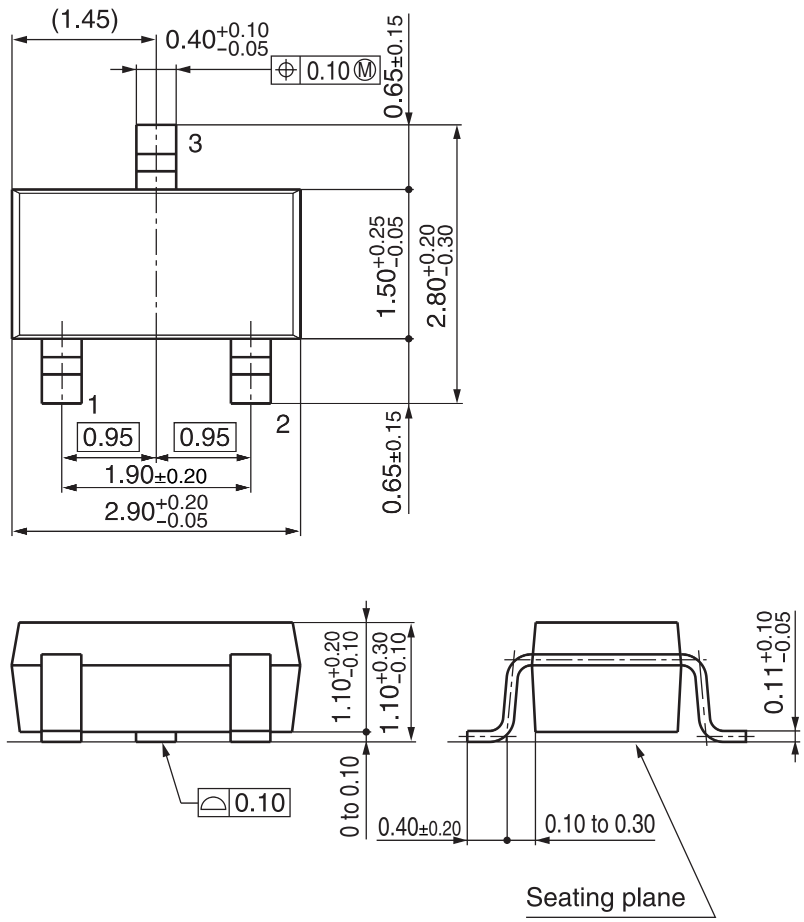


Operating magnetic flux density — Supply voltage



■ New Package Dimensions (Unit: mm)

• MINI-3DA (Lead-free package)



DN6847/SE/S

Wide operating temperature range (–40°C to +100°C) Alternating magnetic field operation

■ Overview

In each of Hall ICs, a Hall element, an amplifier circuit, a Schmidt circuit, a stabilized power supply, and a temperature compensation circuit are integrated on a single chip by IC technique. The Hall element output is amplified by the amplifier circuit, and converted into the corresponding digital signals through the Schmidt circuit so that TTL and MOS IC are directly drivable.

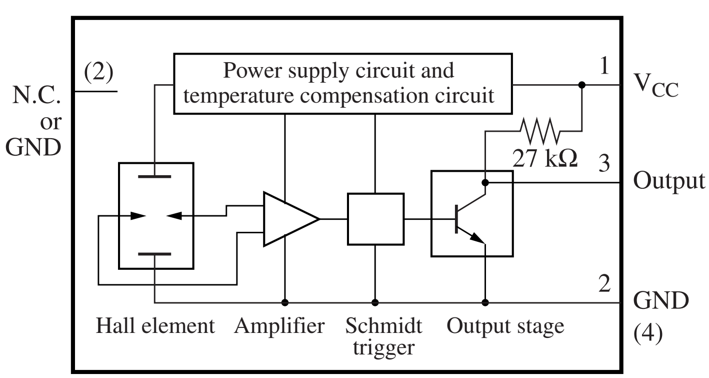
■ Features

- High sensitivity and low drift
- Stabilized temperature characteristics owing to additional integration of temperature compensation circuit.
- Wide operating supply voltage range (V_{CC} = 4.5 V to 16 V)
- Alternating magnetic field operation
- TTL and MOS IC are directly drivable by the output.
- Equipped with an output pull-up resistor (typical 27 kΩ)

■ Applications

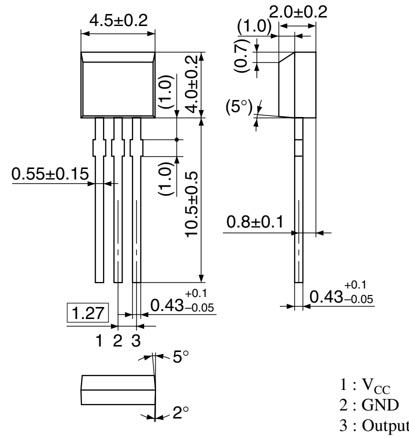
- Speed sensor, position sensor, rotation sensor, keyboard switch, micro switch and the like

■ Block Diagram (DN6847/SE/S)



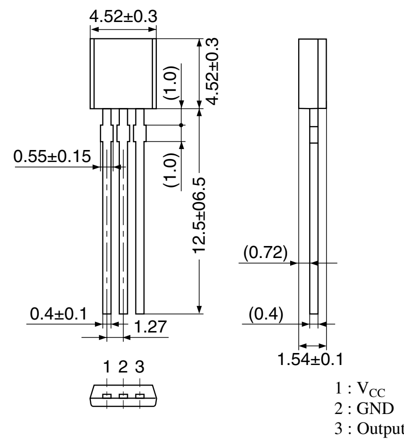
Note) The number in ( ) shows the pin number for the DN6847S.

DN6847 Unit: mm



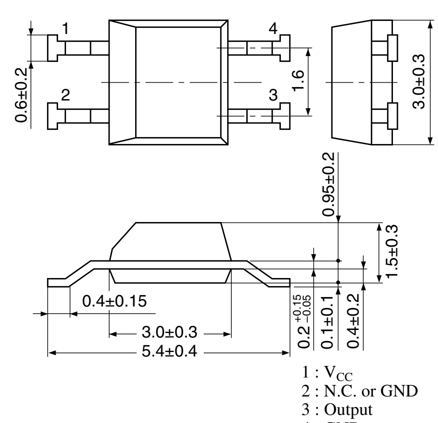
SSIP003-P-0000A

DN6847SE Unit: mm



SSIP003-P-0000C

DN6847S Unit: mm



ESOP004-P-0200

Note) The packages (SSIP003-P-0000A, SSIP003-P-0000C and ESOP004-P-0200) of this product will be changed to lead-free type (SSIP003-P-0000H, SSIP003-P-0000J and ESOP004-P-0200A). See the new package dimensions section later of this datasheet.

■ Absolute Maximum Ratings

Parameter	Symbol	Rating	Unit
Supply voltage	V_{CC}	18	V
Supply current	I_{CC}	8	mA
Circuit current	I_O	20	mA
Power dissipation	P_D	150	mW
Operating ambient temperature	T_{opr}	–40 to +100	°C
Storage temperature	T_{stg}	–55 to +125	°C

Note) This IC is not suitable for car electrical equipment.

■ Recommended Operating Range

Parameter	Symbol	Range	Unit
Supply voltage	V_{CC}	4.5 to 16	V

■ Electrical Characteristics at T_a = 25°C

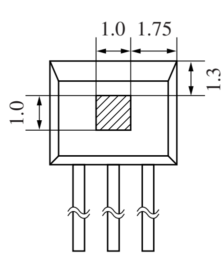
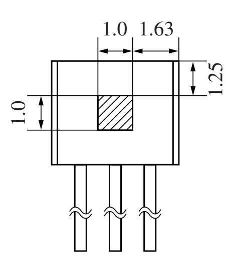
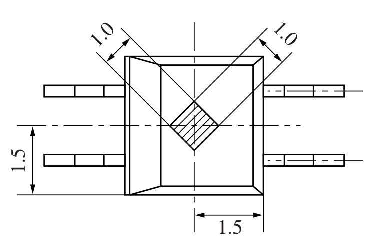
Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Operating magnetic flux density	$B_{1(L\text{-}H)}$	V_{CC} = 12 V	–17.5	–6	—	mT
	$B_{2(H\text{-}L)}$	V_{CC} = 12 V	—	6	17.5	mT
Hysteresis width	BW	V_{CC} = 12 V	7	10	—	mT
Output voltage	V_{OL}	V_{CC} = 4.5 V to 16 V, I_O = 12 mA, B = 17.5 mT	—	—	0.4	V
	V_{OH}	V_{CC} = 16 V, I_O = –30 μA, B = –17.5 mT	14.7	—	—	V
		V_{CC} = 4.5 V, I_O = –30 μA, B = –17.5 mT	2.9	—	—	V
Output short circuit current	$-I_{OS}$	V_{CC} = 16 V, V_O = 0 V, B = –17.5 mT	0.4	—	0.9	mA
Supply current	I_{CC}	V_{CC} = 16 V	1	—	6	mA
		V_{CC} = 4.5 V	1	—	5.5	mA

Note) 1. The variation of operating magnetic flux density does not depend on supply voltage due to its built-in stabilized power source. (V_{CC} should be confined to the range of 4.5 V to 16 V.)
2. A supply current increases by approximately 1 mA when its output level varies from high to low.

■ Technical Data

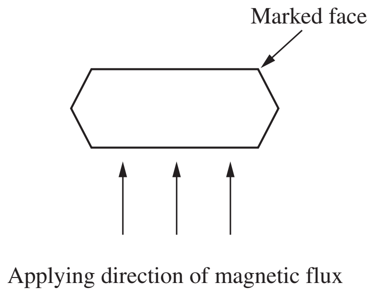
• Position of Hall element (unit: mm)

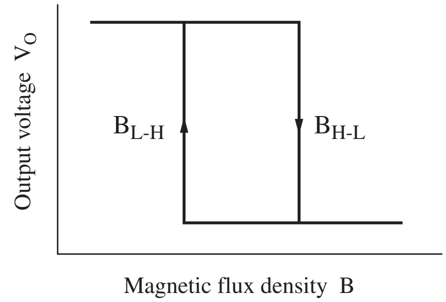
A Hall element is placed on the shaded part in the figure.

DN6847	DN6847SE	DN6847S
		
Distance from package surface to sensor part		
0.7	0.42	0.65

■ Technical Data (continued)

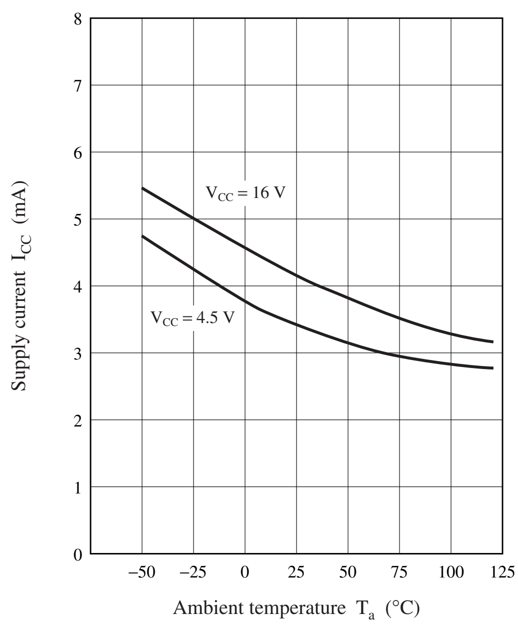
• Magneto-electro conversion characteristics



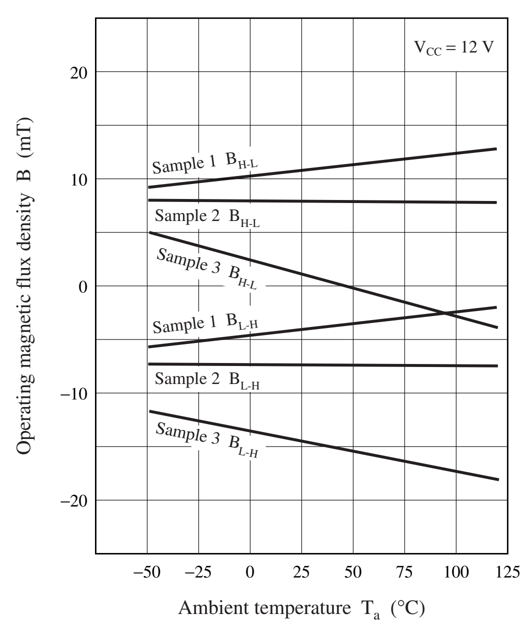


• Main characteristics

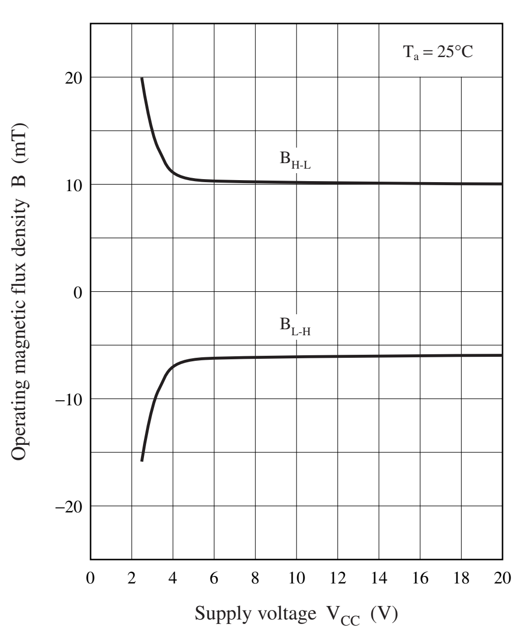
Supply current — Ambient temperature



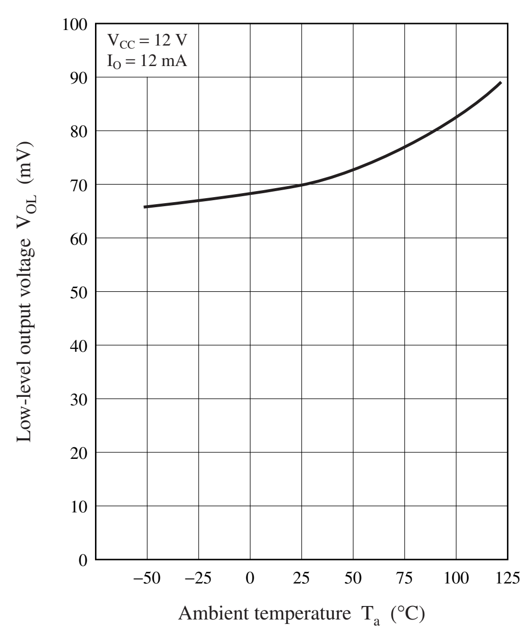
Operating magnetic flux density — Ambient temperature



Operating magnetic flux density — Supply voltage

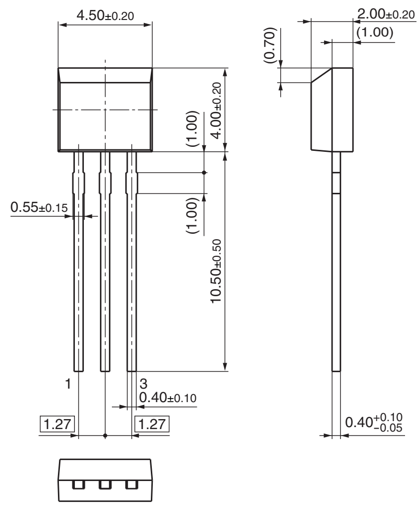


Low-level output voltage — Ambient temperature

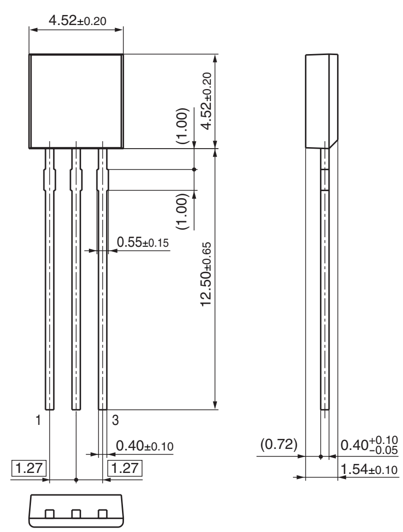


■ New Package Dimensions (Unit: mm)

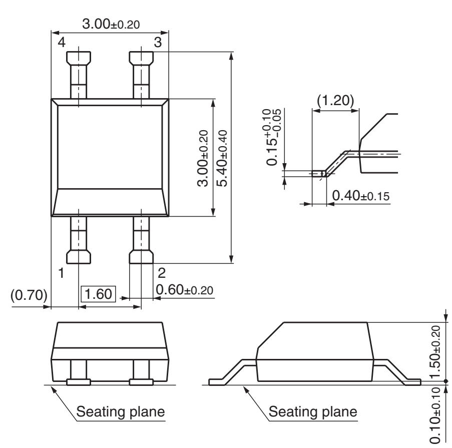
• SSIP003-P-0000H (Lead-free package)



• SSIP003-P-0000J (Lead-free package)



• ESOP004-P-0200A (Lead-free package)



DN6848/SE/S

Wide operating temperature range (–40°C to +100°C) One-way magnetic field operation

■ Overview

In each of Hall ICs, a Hall element, an amplifier circuit, a Schmidt circuit, a stabilized power supply, and a temperature compensation circuit are integrated on a single chip by IC technique. The Hall element output is amplified by the amplifier circuit, and converted into the corresponding digital signals through the Schmidt circuit so that TTL and MOS IC are directly drivable.

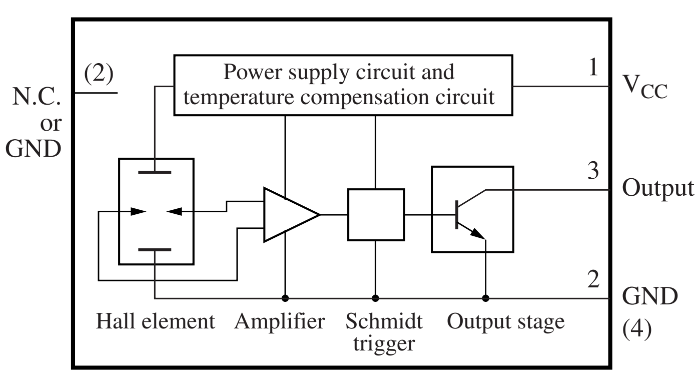
■ Features

- High sensitivity and low drift
- Stabilized temperature characteristics owing to additional integration of temperature compensation circuit.
- Wide operating supply voltage range (V_{CC} = 4.5 V to 16 V)
- One-way magnetic field operation
- TTL and MOS IC are directly drivable by the output.
- Open collector output

■ Applications

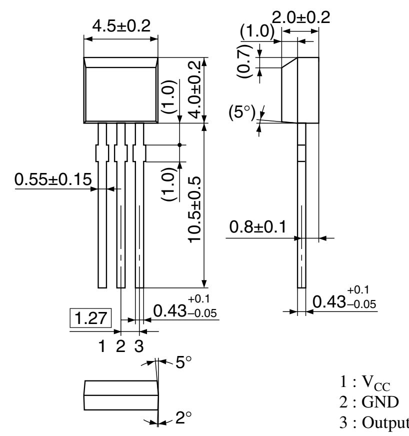
- Speed sensor, position sensor, rotation sensor, keyboard switch, micro switch and the like

■ Block Diagram (DN6848/SE/S)



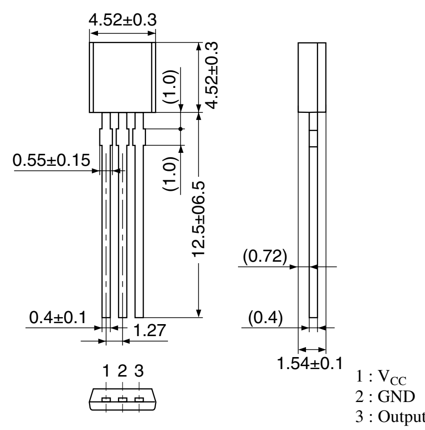
Note) The number in ( ) shows the pin number for the DN6848S.

DN6848 Unit: mm



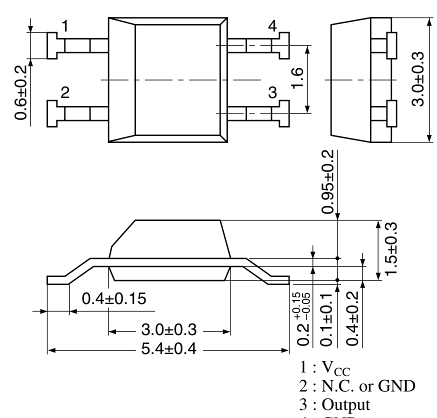
SSIP003-P-0000A

DN6848SE Unit: mm



SSIP003-P-0000C

DN6848S Unit: mm



ESOP004-P-0200

Note) The packages (SSIP003-P-0000A, SSIP003-P-0000C and ESOP004-P-0200) of this product will be changed to lead-free type (SSIP003-P-0000H, SSIP003-P-0000J and ESOP004-P-0200A). See the new package dimensions section later of this datasheet.

■ Absolute Maximum Ratings

Parameter	Symbol	Rating	Unit
Supply voltage	V_{CC}	18	V
Supply current	I_{CC}	8	mA
Circuit current	I_O	20	mA
Power dissipation	P_D	150	mW
Operating ambient temperature	T_{opr}	–40 to +100	°C
Storage temperature	T_{stg}	–55 to +125	°C

Note) This IC is not suitable for car electrical equipment.

■ Recommended Operating Range

Parameter	Symbol	Range	Unit
Supply voltage	V_{CC}	4.5 to 16	V

■ Electrical Characteristics at T_a = 25°C

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Operating magnetic flux density	$B_{1(L\text{-}H)}$	V_{CC} = 12 V	0.5	9	21	mT
	$B_{2(H\text{-}L)}$	V_{CC} = 12 V	1.5	11	22	mT
Hysteresis width	BW	V_{CC} = 12 V	1	2	—	mT
Output voltage	V_{OL}	V_{CC} = 16 V, I_O = 12 mA, B = 22 mT	—	—	0.4	V
		V_{CC} = 4.5 V, I_O = 12 mA, B = 22 mT	—	—	0.4	V
Output current	I_{OH}	V_{CC} = 4.5 V to 16 V, V_O = 16 V, B = 0 mT	—	—	10	µA
Supply current	I_{CC}	V_{CC} = 16 V	—	—	6	mA
		V_{CC} = 4.5 V	—	—	5.5	mA

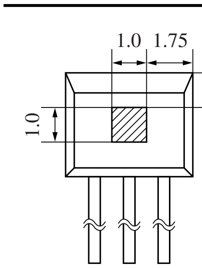
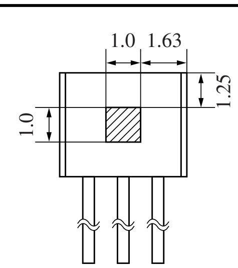
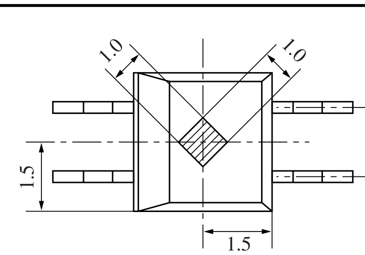
Note) 1. The variation of operating magnetic flux density does not depend on supply voltage due to its built-in stabilized power source. (V_{CC} should be confined to the range of 4.5 V to 16 V.)

2. A supply current increases by approximately 1 mA when its output level varies from high to low.

■ Technical Data

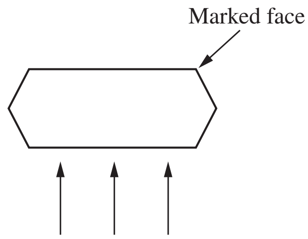
• Position of Hall element (unit: mm)

A Hall element is placed on the shaded part in the figure.

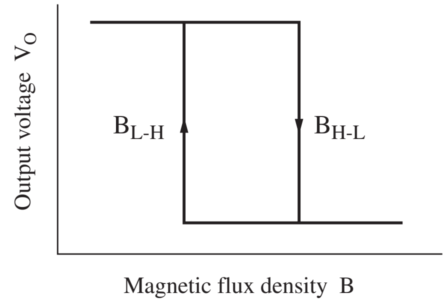
DN6848	DN6848SE	DN6848S
		
Distance from package surface to sensor part		
0.7	0.42	0.65

■ Technical Data (continued)

• Magneto-electro conversion characteristics

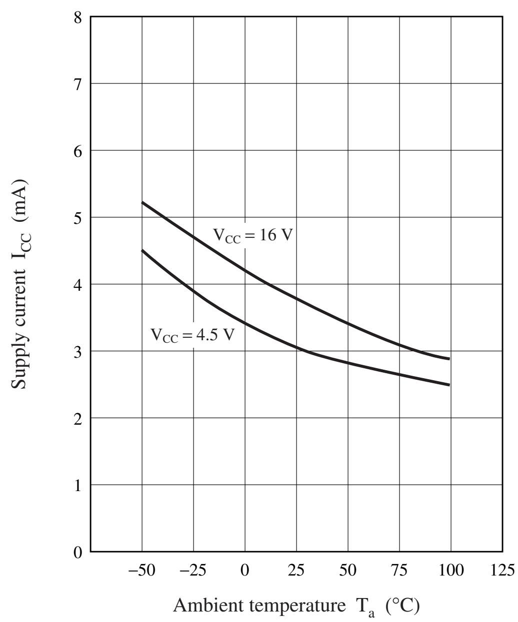


Applying direction of magnetic flux

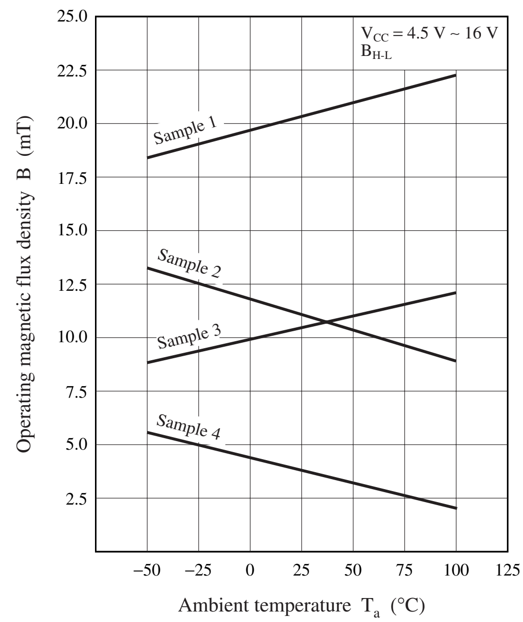


• Main characteristics

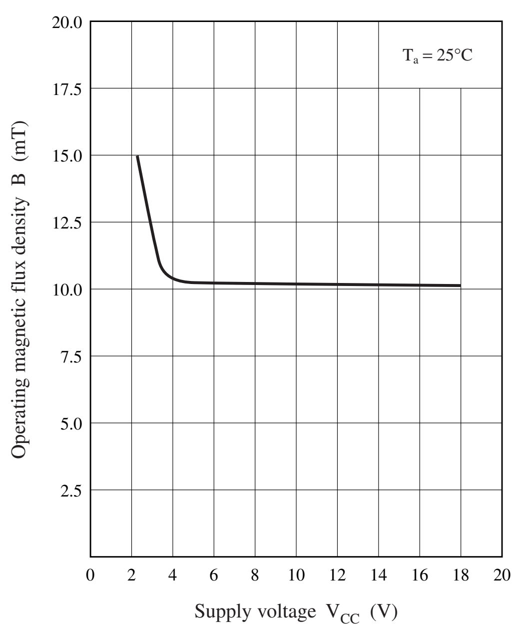
Supply current — Ambient temperature



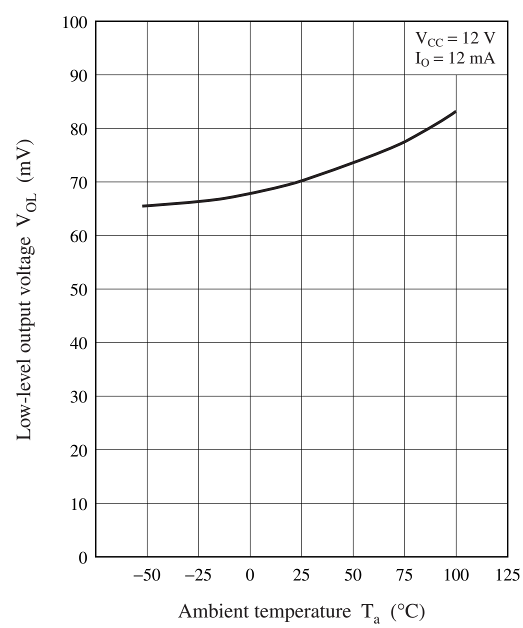
Operating magnetic flux density — Ambient temperature



Operating magnetic flux density — Supply voltage

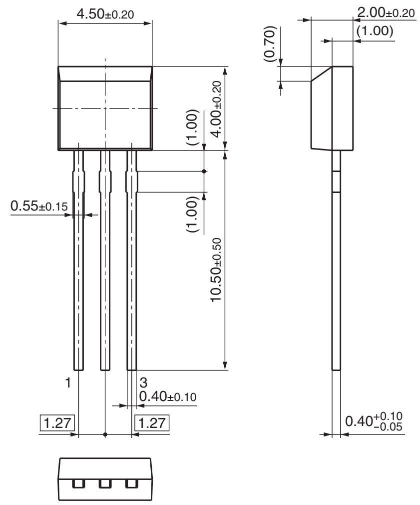


Low-level output voltage — Ambient temperature

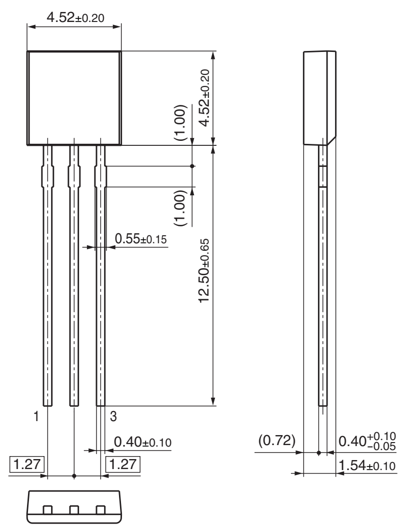


■ New Package Dimensions (Unit: mm)

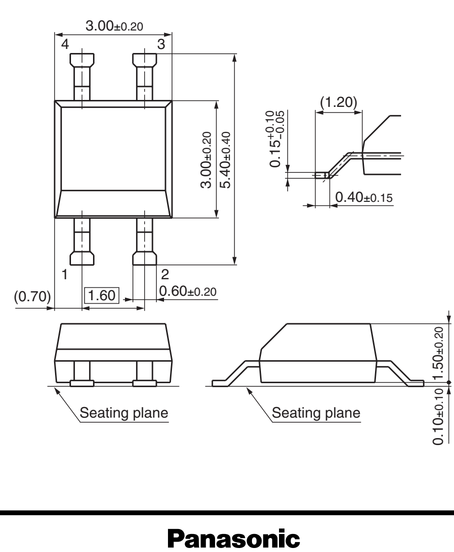
- SSIP003-P-0000H (Lead-free package)



- SSIP003-P-0000J (Lead-free package)



- ESOP004-P-0200A (Lead-free package)



DN6849/SE/S

Wide operating temperature range (–40°C to +100°C) Alternating magnetic field operation

■ Overview

In each of Hall ICs, a Hall element, an amplifier circuit, a Schmidt circuit, a stabilized power supply, and a temperature compensation circuit are integrated on a single chip by IC technique. The Hall element output is amplified by the amplifier circuit, and converted into the corresponding digital signals through the Schmidt circuit so that TTL and MOS IC are directly drivable.

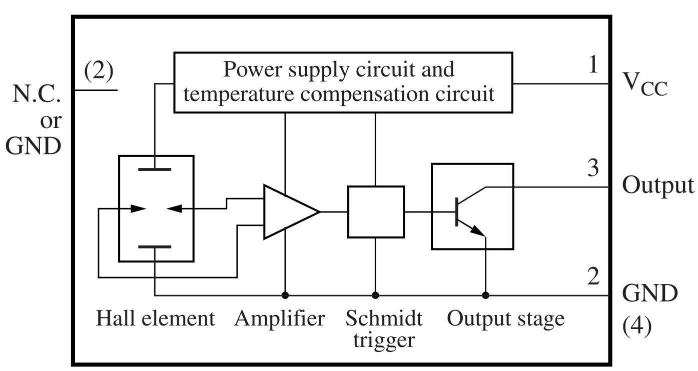
■ Features

- High sensitivity and low drift
- Stabilized temperature characteristics owing to additional integration of temperature compensation circuit.
- Wide operating supply voltage range (V_{CC} = 4.5 V to 16 V)
- Alternating magnetic field operation
- TTL and MOS IC are directly drivable by the output.
- Open collector output

■ Applications

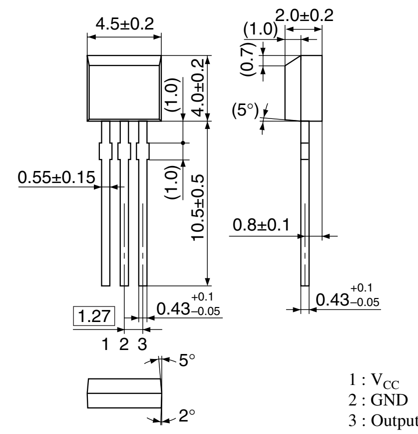
- Speed sensor, position sensor, rotation sensor, keyboard switch, micro switch and the like

■ Block Diagram (DN6849/SE/S)



Note) The number in ( ) shows the pin number for the DN6849S.

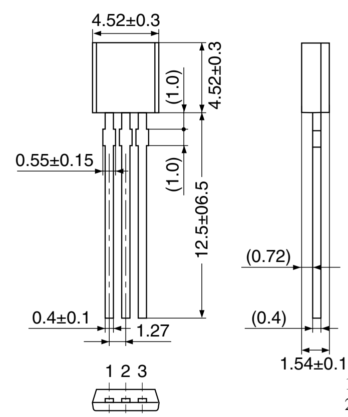
DN6849 Unit: mm



1 : V_{CC}
2 : GND
3 : Output

SSIP003-P-0000A

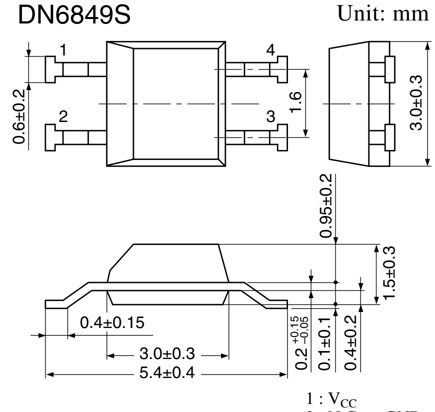
DN6849SE Unit: mm



1 : V_{CC}
2 : GND
3 : Output

SSIP003-P-0000C

DN6849S Unit: mm



1 : V_{CC}
2 : N.C. or GND
3 : Output
4 : GND

ESOP004-P-0200

Note) The packages (SSIP003-P-0000A, SSIP003-P-0000C and ESOP004-P-0200) of this product will be changed to lead-free type (SSIP003-P-0000H, SSIP003-P-0000J and ESOP004-P-0200A). See the new package dimensions section later of this datasheet.

■ Absolute Maximum Ratings

Parameter	Symbol	Rating	Unit
Supply voltage	V_{CC}	18	V
Supply current	I_{CC}	8	mA
Circuit current	I_O	20	mA
Power dissipation	P_D	150	mW
Operating ambient temperature	T_{opr}	–40 to +100	°C
Storage temperature	T_{stg}	–55 to +125	°C

Note) This IC is not suitable for car electrical equipment.

■ Recommended Operating Range

Parameter	Symbol	Range	Unit
Supply voltage	V_{CC}	4.5 to 16	V

■ Electrical Characteristics at T_a = 25°C

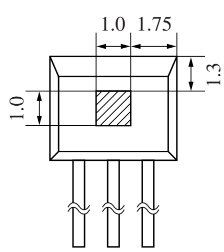
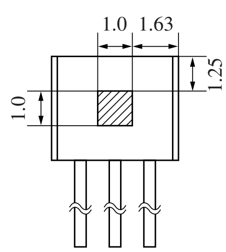
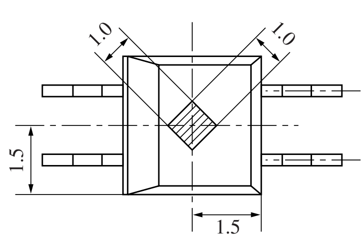
Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Operating magnetic flux density	$B_{1(L-H)}$	V_{CC} = 12 V	–17.5	–6	—	mT
	$B_{2(H-L)}$	V_{CC} = 12 V	—	6	17.5	mT
Hysteresis width	BW	V_{CC} = 12 V	7	10	—	mT
Output voltage	V_{OL}	V_{CC} = 4.5 V to 16 V, I_O = 12 mA, B = 17.5 mT	—	—	0.4	V
Output current	I_{OH}	V_{CC} = 4.5 V to 16 V, V_O = 16 V, B = −17.5 mT	—	—	10	µA
Supply current	I_{CC}	V_{CC} = 16 V	—	—	6	mA
		V_{CC} = 4.5 V	—	—	5.5	mA

Note) 1. The variation of operating magnetic flux density does not depend on supply voltage due to its built-in stabilized power source. (V_{CC} should be confined to the range of 4.5 V to 16 V.)
2. A supply current increases by approximately 1 mA when its output level varies from high to low.

■ Technical Data

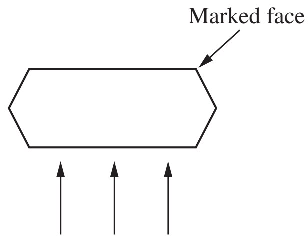
• Position of Hall element (unit: mm)

A Hall element is placed on the shaded part in the figure.

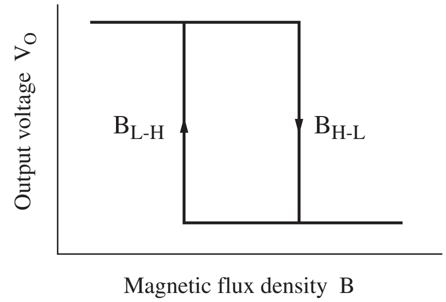
DN6849	DN6849SE	DN6849S
		
Distance from package surface to sensor part		
0.7	0.42	0.65

■ Technical Data (continued)

- Magneto-electro conversion characteristics

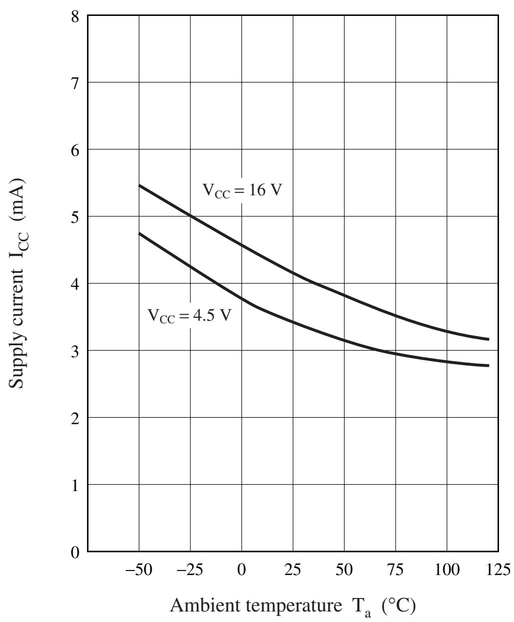


Applying direction of magnetic flux

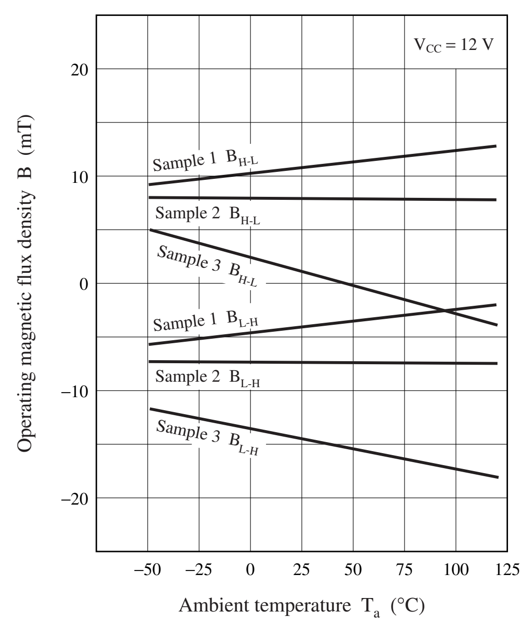


- Main characteristics

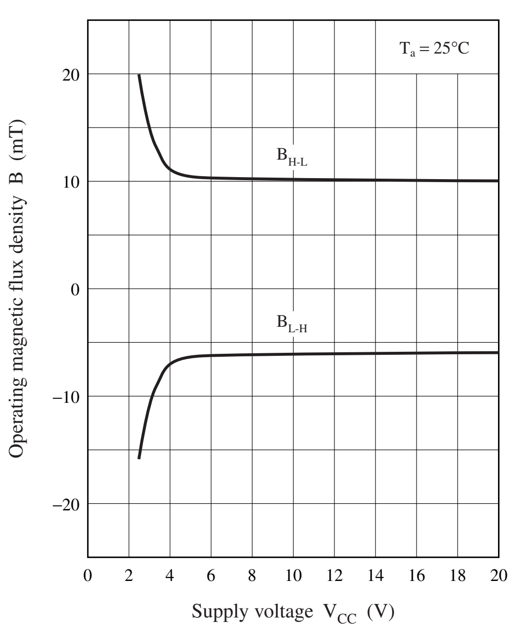
Supply current — Ambient temperature



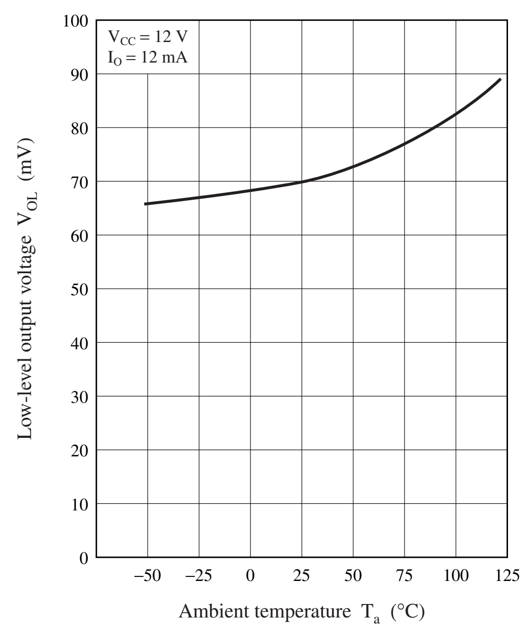
Operating magnetic flux density — Ambient temperature



Operating magnetic flux density — Supply voltage

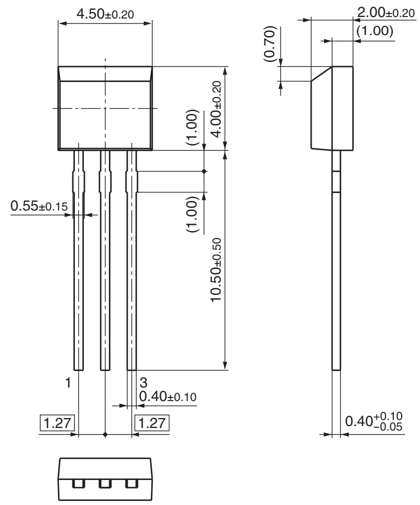


Low-level output voltage — Ambient temperature

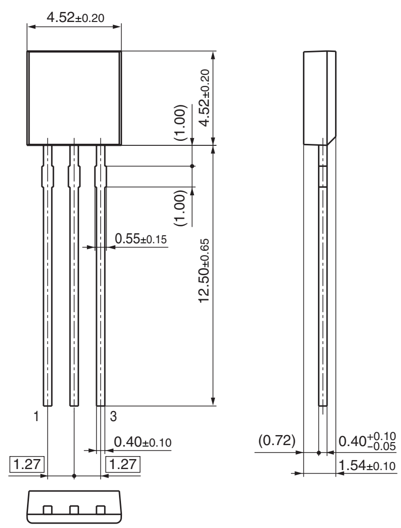


■ New Package Dimensions (Unit: mm)

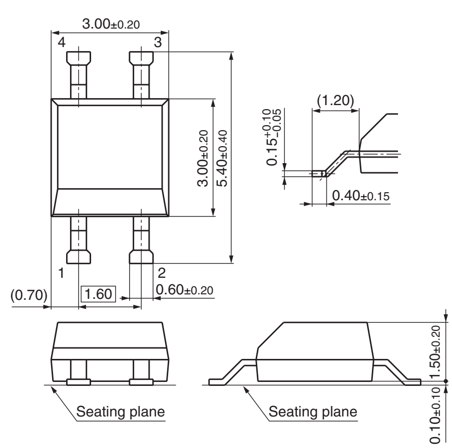
• SSIP003-P-0000H (Lead-free package)



• SSIP003-P-0000J (Lead-free package)



• ESOP004-P-0200A (Lead-free package)



DN6851

Switch type, Wide operating supply voltage range (V_{CC} = 3.6 V to 16 V) Alternating magnetic field operation

■ Overview

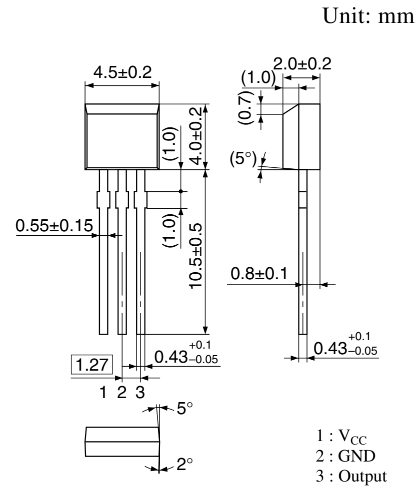
DN6851 is a semiconductor integrated circuit utilizing the Hall effect. It has been so designed as to operate in the alternating magnetic field especially at low supply voltage. This Hall IC is suitable for application to various kinds of sensors, contactless switches, and the like.

■ Features

- Wide supply voltage range of 3.6 V to 16 V
- Alternating magnetic field operation
- TTL and MOS IC are directly drivable by the output.
- The life is semipermanent because it employs contactless parts.
- SSIP003-P-0000A package
- Equipped with an output pull-up resistor (typical 27 kΩ)

■ Applications

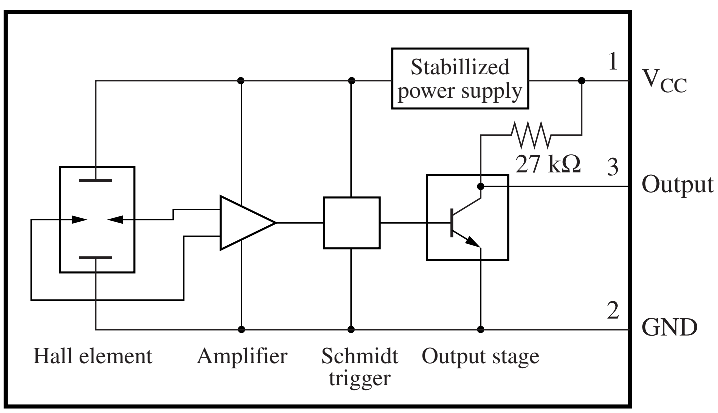
- Speed sensor, position sensor, rotation sensor, keyboard switch, micro switch and the like



SSIP003-P-0000A

Note) The package of this product will be changed to lead-free type (SSIP003-P-0000H). See the new package dimensions section later of this datasheet.

■ Block Diagram



■ Absolute Maximum Ratings

Parameter	Symbol	Rating	Unit
Supply voltage	V_{CC}	18	V
Supply current	I_{CC}	8	mA
Circuit current	I_O	20	mA
Power dissipation	P_D	100	mW
Operating ambient temperature	T_{opr}	–40 to +85	°C
Storage temperature	T_{stg}	–55 to +125	°C

Note) This IC is not suitable for car electrical equipment.

■ Recommended Operating Range

Parameter	Symbol	Range	Unit
Supply voltage	V_{CC}	3.6 to 16	V

■ Electrical Characteristics at $T_a = 25°C$

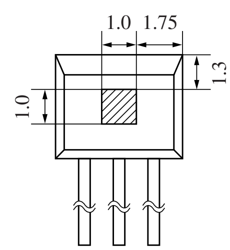
Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Operating magnetic flux density	$B_{1(L-H)}$	V_{CC} = 12 V	–30	—	—	mT
	$B_{2(H-L)}$	V_{CC} = 12 V	—	—	30	mT
Low-level output voltage	V_{OL}	V_{CC} = 16 V, I_O = 12 mA, B = 30 mT	—	—	0.4	V
		V_{CC} = 3.6 V, I_O = 12 mA, B = 30 mT	—	—	0.4	V
High-level output voltage	V_{OH}	V_{CC} = 16 V, I_O = –30 µA, B = –30 mT	14.6	—	—	V
		V_{CC} = 3.6 V, I_O = –30 µA, B = –30 mT	2.2	—	—	V
Output short circuit current	$-I_{OS}$	V_{CC} = 16 V, V_O = 0 V, B = –30 mT	0.4	—	0.9	mA
Supply current	I_{CC}	V_{CC} = 16 V	—	—	6	mA
		V_{CC} = 3.6 V	—	—	5.5	mA

Note) 1. An 'A' rank type which operating magnetic flux density is ±20 mT is also available.
2. The variation of operating magnetic flux density does not depend on supply voltage due to its built-in stabilized power source. (V_{CC} should be confined to the range of 3.6 V to 16 V.)
3. A supply current increases by approximately 1 mA when its output level varies from high to low.

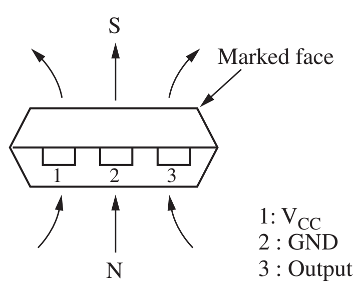
■ Technical Data

• Position of Hall element (unit: mm)

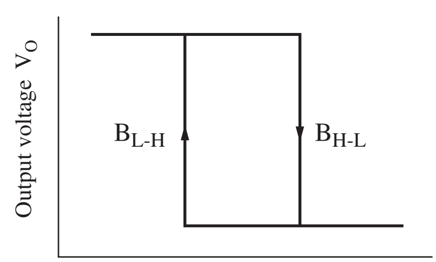
Distance from package surface to sensor part: 0.7 mm
A Hall element is placed on the shaded part in the figure.



• Magneto-electro conversion characteristics



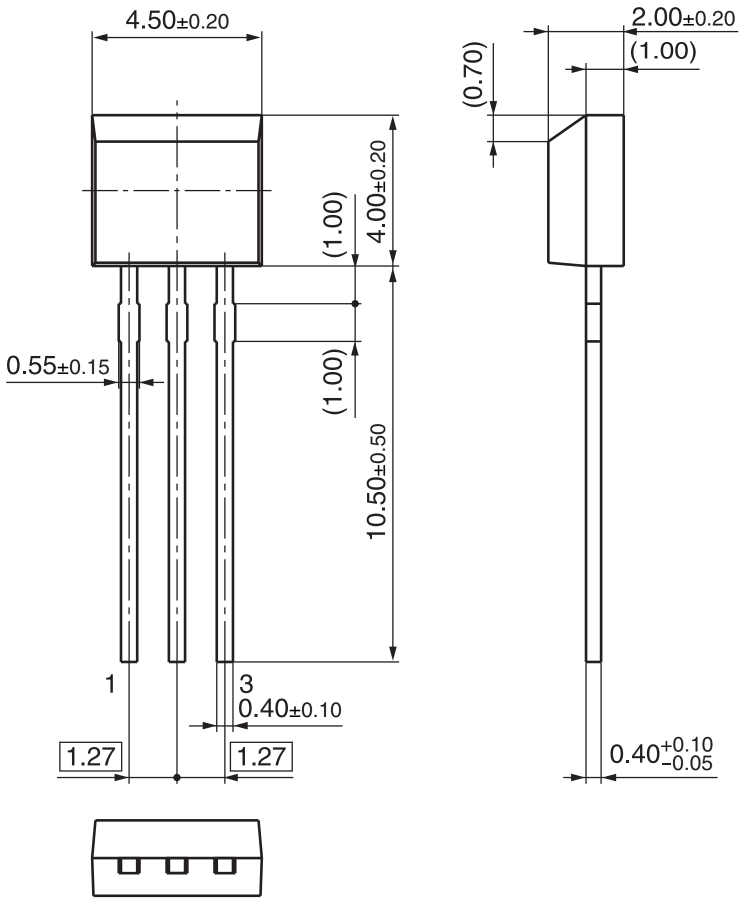
Applying direction of magnetic flux



Magnetic flux density B

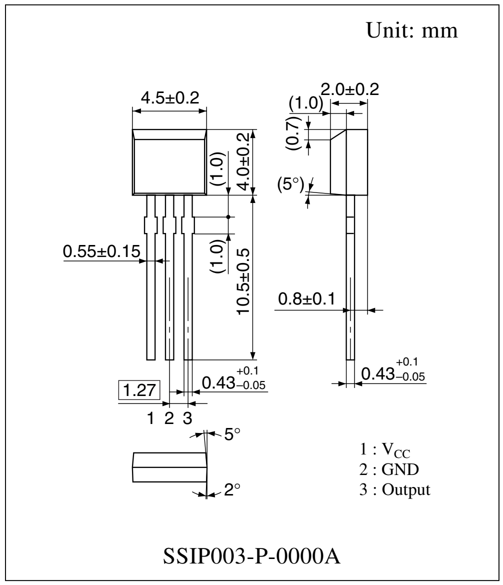
■ New Package Dimensions (Unit: mm)

• SSIP003-P-0000H (Lead-free package)



DN6852

Switch type, Wide operating supply voltage range (V_{CC} = 3.6 V to 16 V) One-way magnetic field operation



Note) The package of this product will be changed to lead-free type (SSIP003-P-0000H). See the new package dimensions section later of this datasheet.

■ Overview

DN6852 is a semiconductor integrated circuit utilizing the Hall effect. It has been so designed as to operate in the unidirectional magnetic field especially at low supply voltage. This Hall IC is suitable for application to various kinds of sensors, contactless switches, and the like.

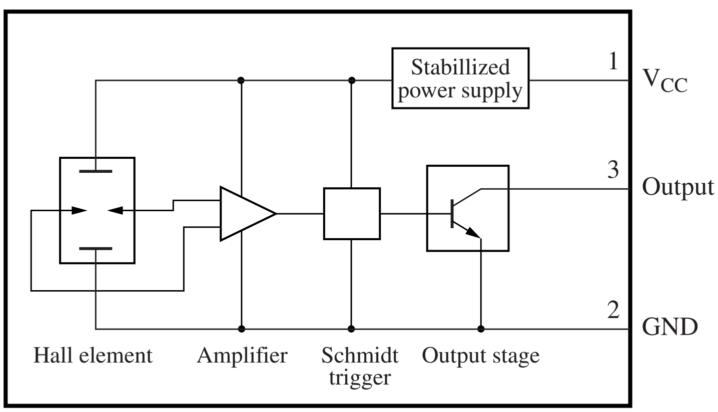
■ Features

- Wide supply voltage range of 3.6 V to 16 V
- Unidirectional magnetic field operation
- TTL and MOS IC are directly drivable by the output.
- The life is semipermanent because it employs contactless parts.
- SSIP003-P-0000A package
- Open collector output

■ Applications

- Speed sensor, position sensor, rotation sensor, keyboard switch, micro switch and the like

■ Block Diagram



■ Absolute Maximum Ratings

Parameter	Symbol	Rating	Unit
Supply voltage	V_{CC}	18	V
Supply current	I_{CC}	8	mA
Circuit current	I_O	20	mA
Power dissipation	P_D	100	mW
Operating ambient temperature	T_{opr}	–40 to +85	°C
Storage temperature	T_{stg}	–55 to +125	°C

Note) This IC is not suitable for car electrical equipment.

■ Recommended Operating Range

Parameter	Symbol	Range	Unit
Supply voltage	V_{CC}	3.6 to 16	V

■ Electrical Characteristics at T_a = 25°C

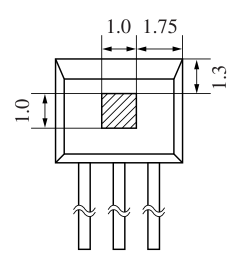
Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Operating magnetic flux density	$B_{1(L-H)}$	V_{CC} = 12 V	10	—	—	mT
	$B_{2(H-L)}$	V_{CC} = 12 V	—	—	60	mT
Low-level output voltage	V_{OL}	V_{CC} = 16 V, I_O = 12 mA, B = 60 mT	—	—	0.4	V
		V_{CC} = 3.6 V, I_O = 12 mA, B = 60 mT	—	—	0.4	V
Output current	I_{OH}	V_{CC} = 16 V, V_O = 18 V, B = 10 mT	—	—	10	V
		V_{CC} = 3.6 V, V_O = 18 V, B = 10 mT	—	—	10	V
Supply current	I_{CC}	V_{CC} = 16 V	—	—	6	mA
		V_{CC} = 3.6 V	—	—	5.5	mA

Note) 1. An 'A' rank type which operating magnetic flux density is ±20 mT is also available.
2. The variation of operating magnetic flux density does not depend on supply voltage due to its built-in stabilized power source. (V_{CC} should be confined to the range of 3.6 V to 16 V.)
3. A supply current increases by approximately 1 mA when its output level varies from high to low.

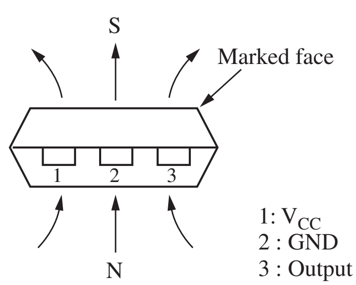
■ Technical Data

• Position of Hall element (unit: mm)

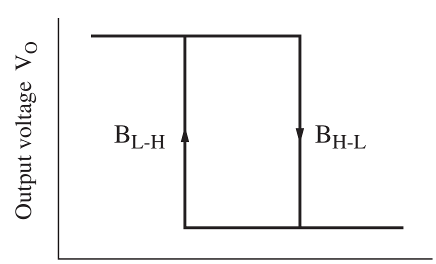
Distance from package surface to sensor part: 0.7 mm
A Hall element is placed on the shaded part in the figure.



• Magneto-electro conversion characteristics



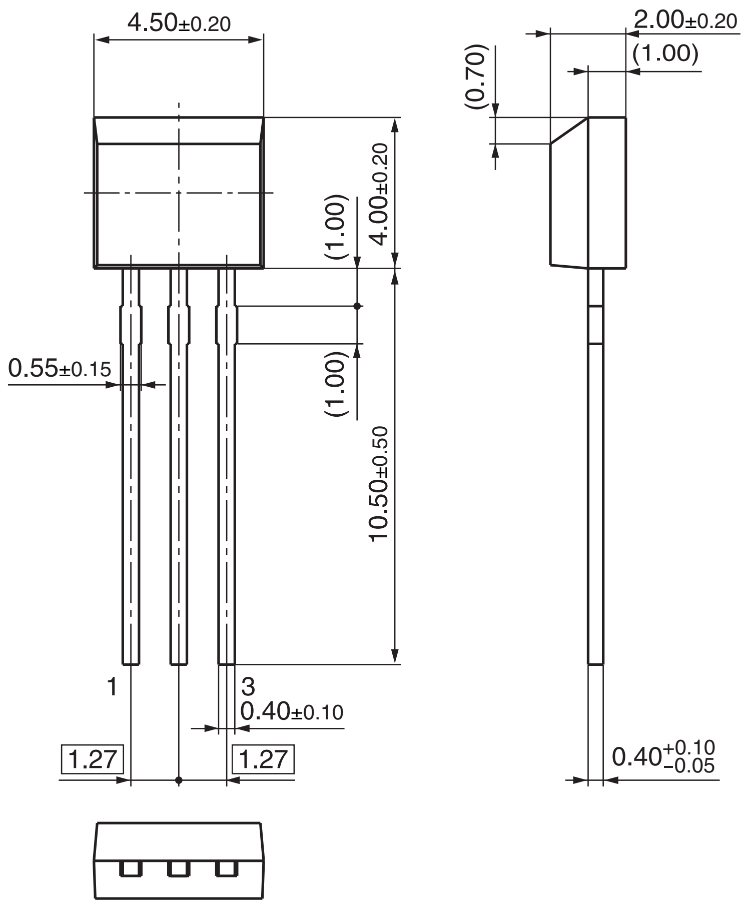
Applying direction of magnetic flux



Magnetic flux density B

■ New Package Dimensions (Unit: mm)

• SSIP003-P-0000H (Lead-free package)

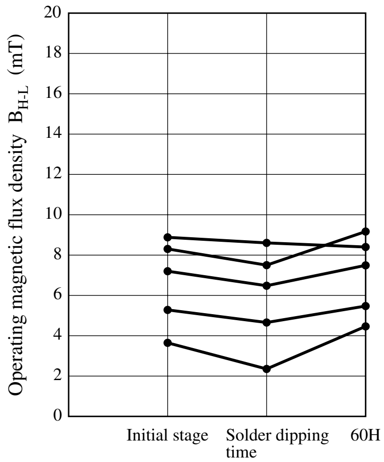


Operating Sensitivity and Reliability Test Result

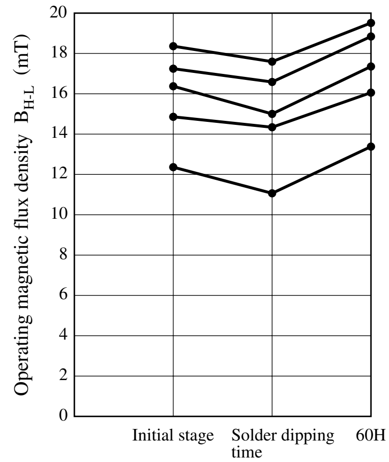
Generally speaking, a Hall IC is quite sensitive to mechanical stress and thermal stress. We would like each user to design the concerning sets with sufficient margins by referring to the data on magnetic flux density variation in the reliability test result.

Variation of operating magnetic flux density in reliability test

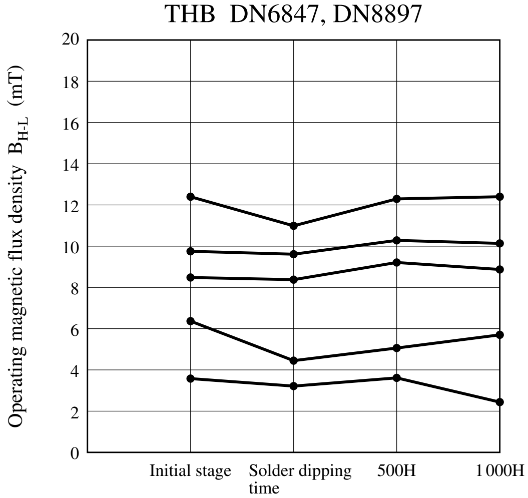
PCT DN6847, DN8897



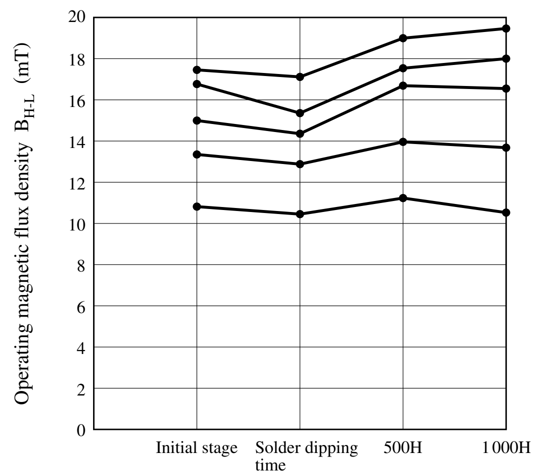
PCT DN6848



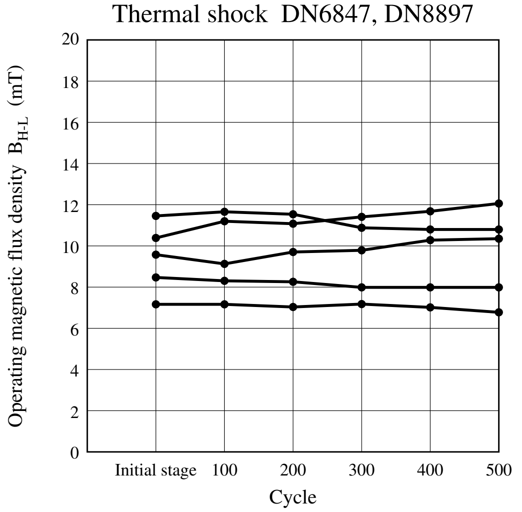
THB DN6847, DN8897



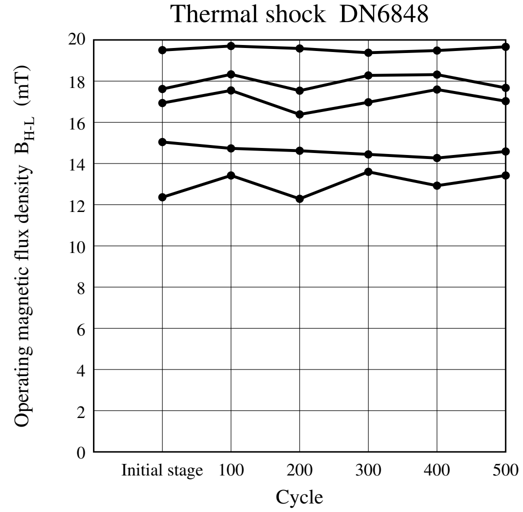
THB DN6848



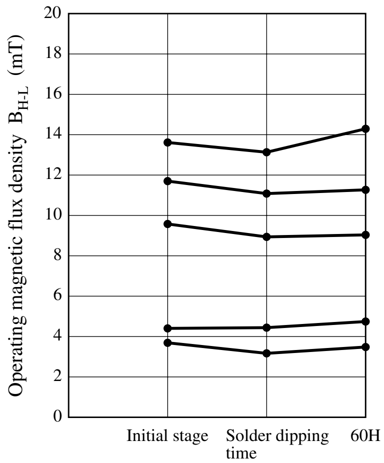
Thermal shock DN6847, DN8897



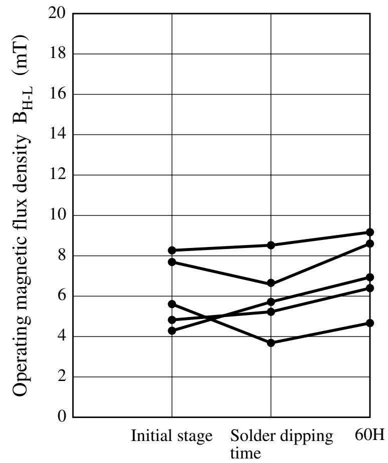
Thermal shock DN6848



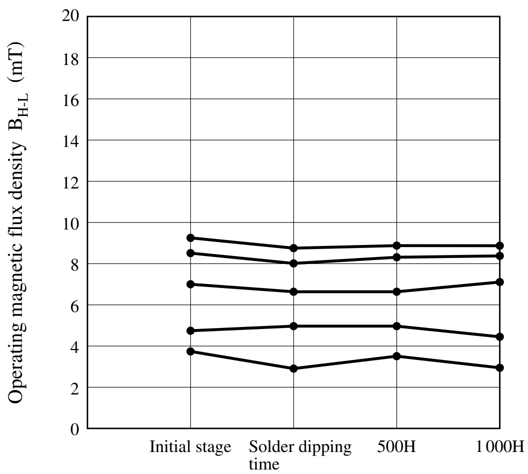
PCT DN6849, DN8899



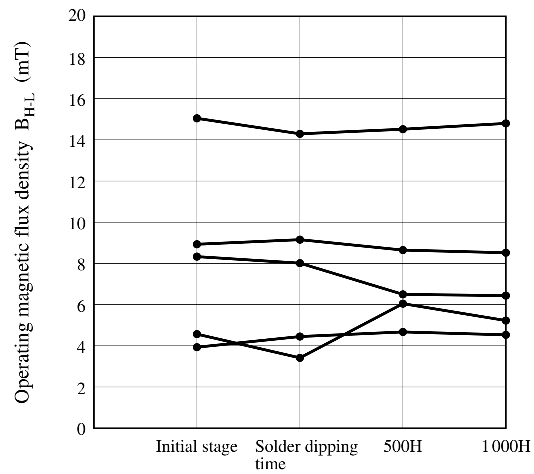
PCT DN6847SE, DN8897SE



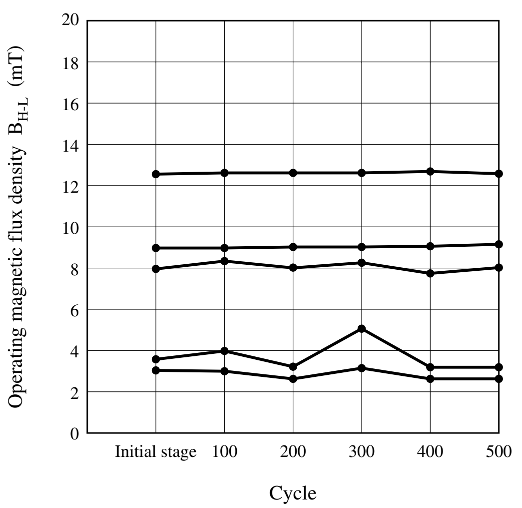
THB DN6849, DN8899



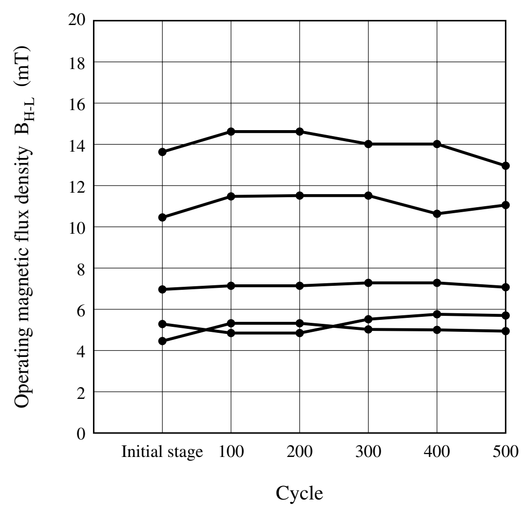
THB DN6847SE, DN8897SE



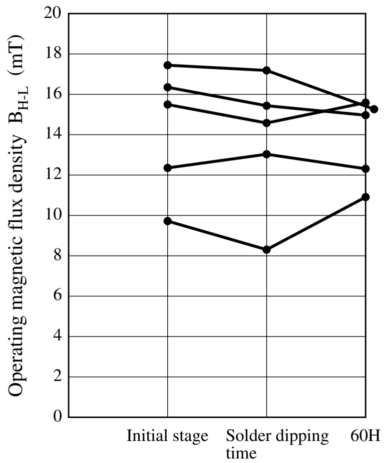
Thermal shock DN6849, DN8899



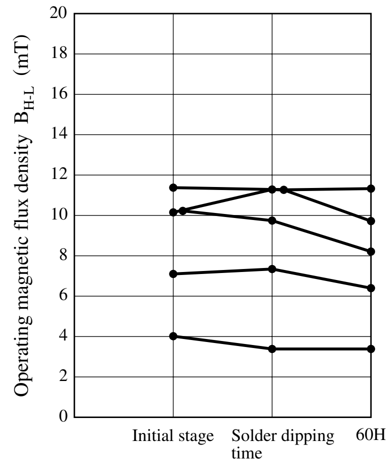
Thermal shock DN6847SE, DN8897SE



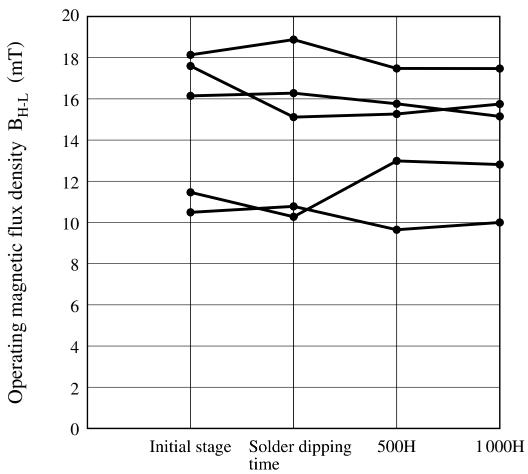
PCT DN6848SE



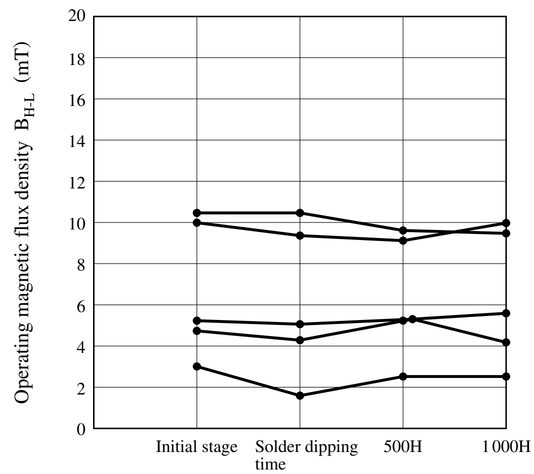
PCT DN6849SE, DN8899SE



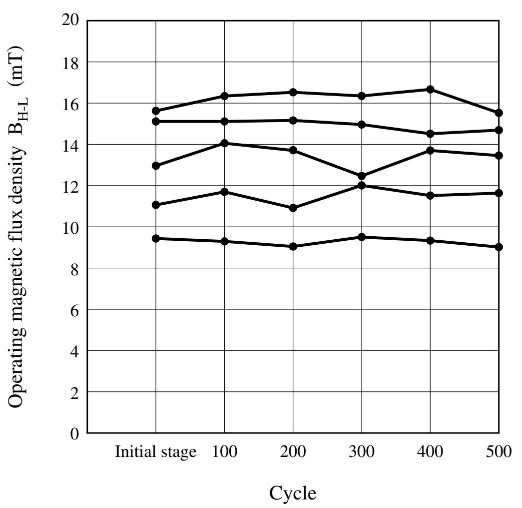
THB DN6848SE



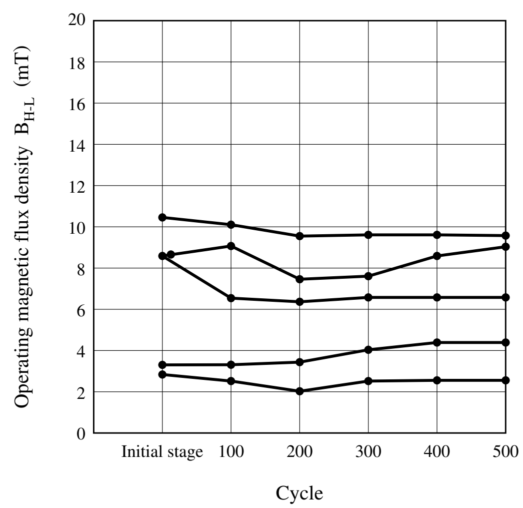
THB DN6849SE, DN8899SE



Thermal shock DN6848SE



Thermal shock DN6849SE, DN8899SE



• Test conditions

Parameter	Condition
Solder dipping	T_a = 260°C 5 s Dip all the wires in solder bath (The conditions of the soldering in actual set.)
PCT	2 atms 121°C
THB	T_a = 85°C RH = 85% V_{CC} = 16 V
Thermal shock (Gaseous phase)	−65°C 30 minutes +150°C 30 minutes